

Luna Innovations seminar

August 18 2008

SAND2008-5312P

Robert Klein

Graduate and postdoctoral work



DEPARTMENT OF
**MATERIALS
SCIENCE AND
ENGINEERING**
COLLEGE OF EARTH AND
MINERAL SCIENCES

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Mike Lanagan, Feng Xia,
Cheng Huang, Kailiang Ren,
Francois Bauer

Jim Runt*

Ralph Colby, Harry Allcock,
Paul Painter, Ron Hedden,
Pornpen Atorngitjawat, Shihai
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**Sandia
National
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Joe Lenhart*

Phil Cole, Mat Celina, Jim
Aubert, Lothar Bieg, Bob
Anderson, Doug Adolf,
Randy Mrozek, John
Schroeder, Shana Cole,
Mike Belcher, Mark Stavig



Dan Fischer
Cherno Jaye, Zugen Fu

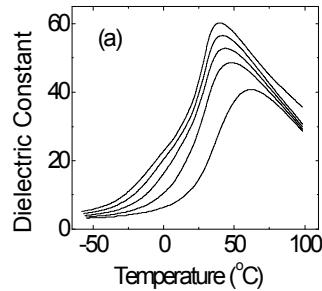
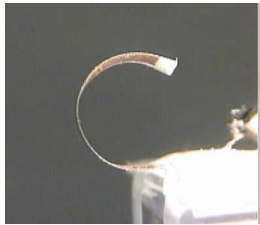
University of California, Santa Barbara
CHEMICAL ENGINEERING

(undergraduate)

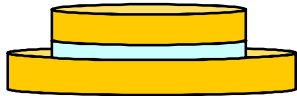
***Advisors**

Sandia is a multiprogram laboratory operated by Sandia Corporation, a Lockheed Martin Company, for the United States Department of Energy's National Nuclear Security Administration under contract DE-AC04-94AL85000

Highlights of my past and present research in organic materials

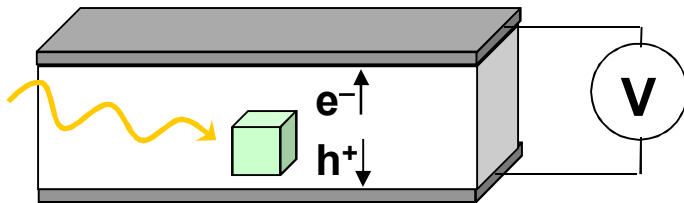


PVDF-based terpolymers for electroactive transducers and high ϵ capacitors

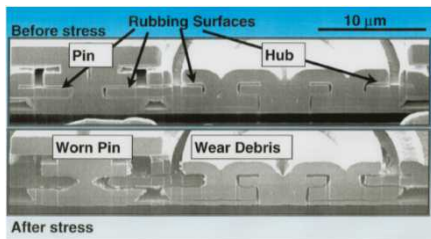


$$\epsilon^*(f, T)$$

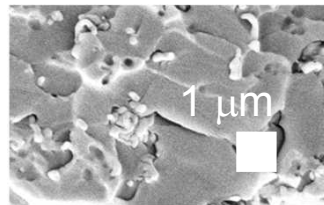
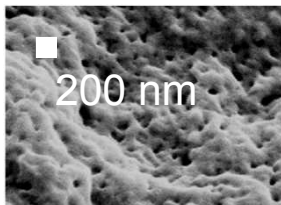
Polymer and ion dynamics in ionomers and polymer electrolytes



Radiation tolerance in polymer dielectrics*



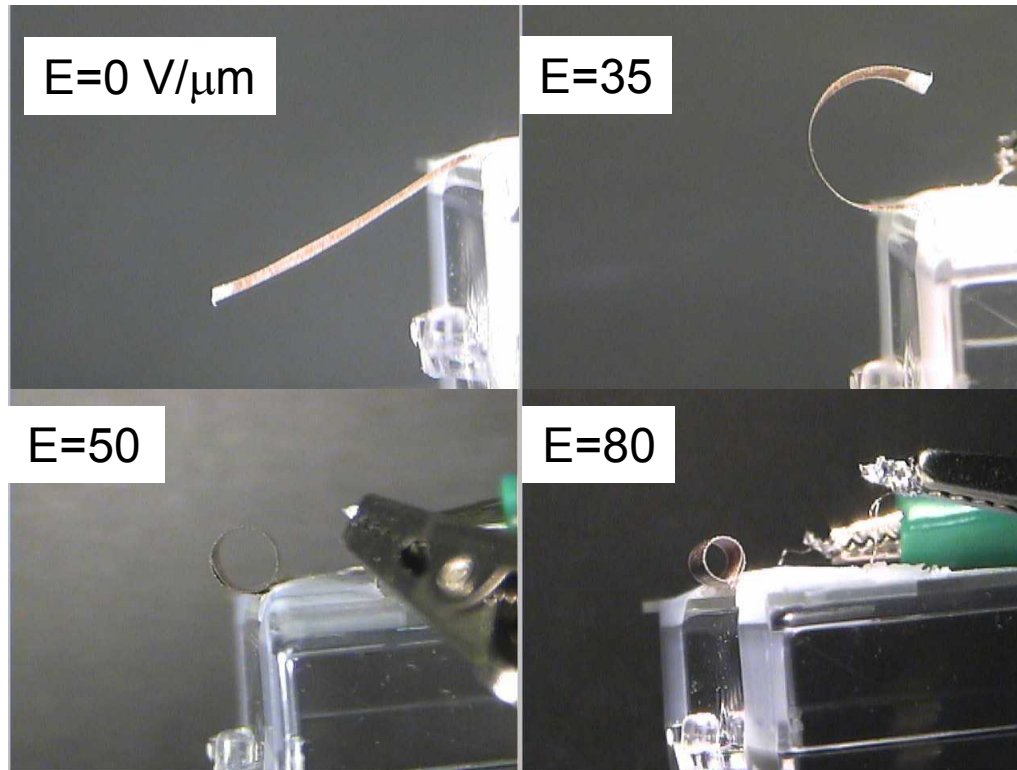
Self-assembled monolayers for anti-stiction in MEMS



Polymer composites: porous and alumina filled epoxies

Modified PVDF-TrFE offers a high dielectric constant and very high electroactive strain

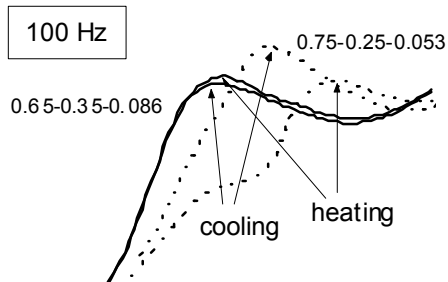
Unimorph: thickness 21 μm , length 22 mm



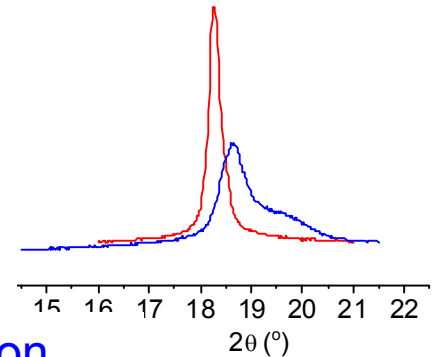
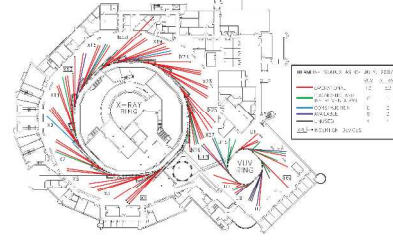
P(VDF-TrFE-CFE) 62/38/4 Terpolymer

Source: Qiming Zhang, PSU

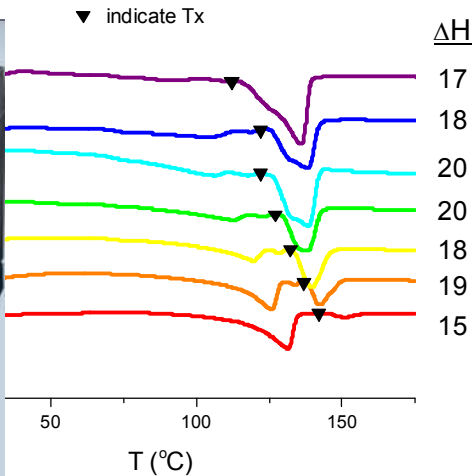
PVDF-based EAPs and dielectric materials: Characterization techniques



HP 4284A dielectric analyzer with
temperature chamber

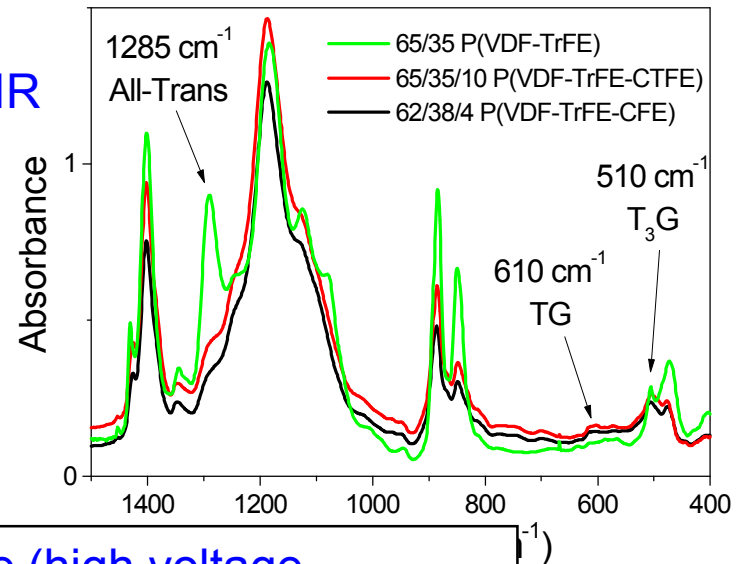


WAXD by synchrotron
(Brookhaven) and Cu-Kα



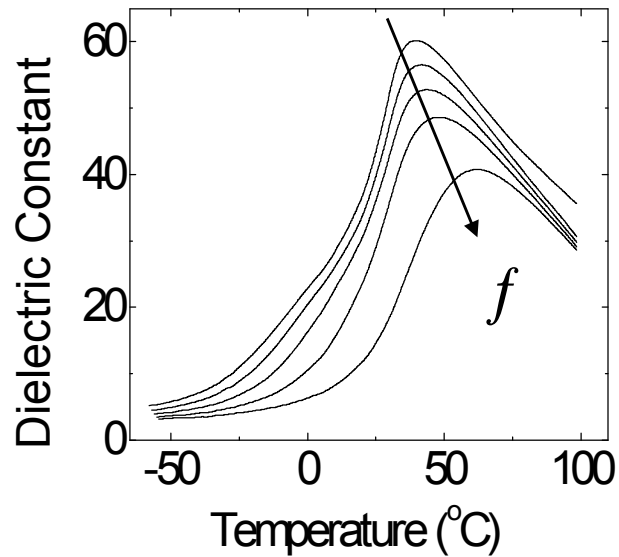
DSC

FT-IR

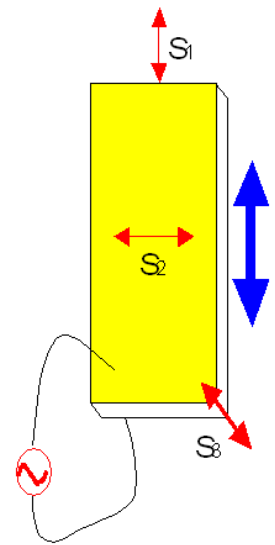
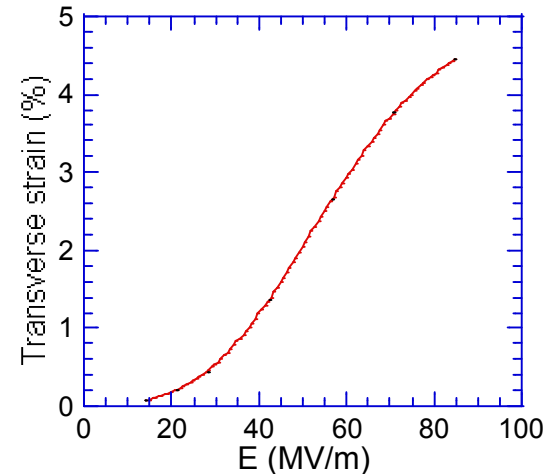
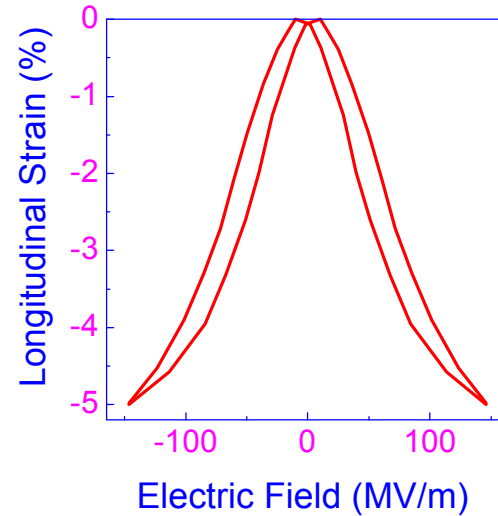


Strain measurement device (high voltage
electrodes, laser interferometer, lock-in amplifier)

Modified PVDF-TrFE offers a high dielectric constant and very high electroactive strain



High ϵ increases EAP efficiency and makes a good capacitor

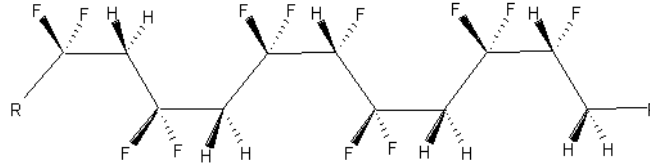


P(VDF-TrFE-CFE) 62/38/4 Terpolymer

Controlled defects in the polymer chain enhance the morphological transitions

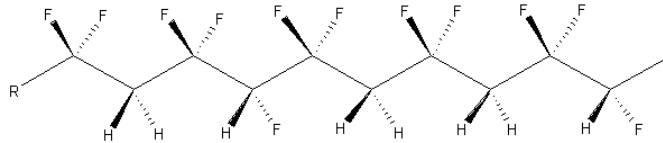
at 25 °C

PVDF: α phase



(can be poled to β phase,
but permanent transition
= ferroelectric)

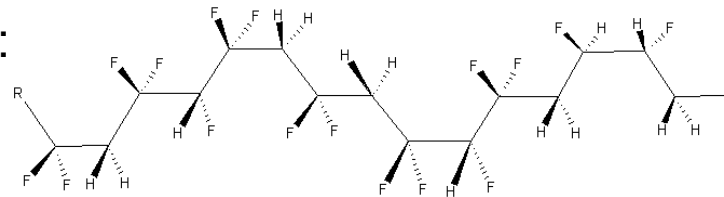
PVDF-TrFE: β
phase, with
large domains



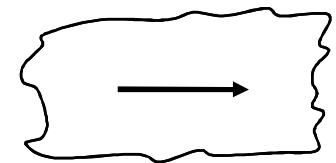
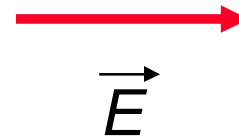
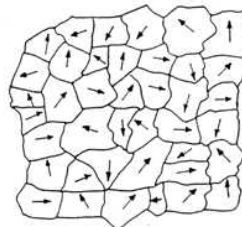
(transitions to α phase upon
heating
= ferroelectric and
paraelectric)

Add irradiation or
chemical defects

Defected PVDF-TrFE:
 $\beta + \gamma$ phases, with
small domains



(transitions to β phase upon
electric field
= relaxor ferroelectric)



Macroscopic strain

PVDF-based EAPs and dielectric materials: Future directions

Variations on the PVDF-terpolymer are being commercialized now for capacitor applications (Strategic Polymer Sciences, Inc.)

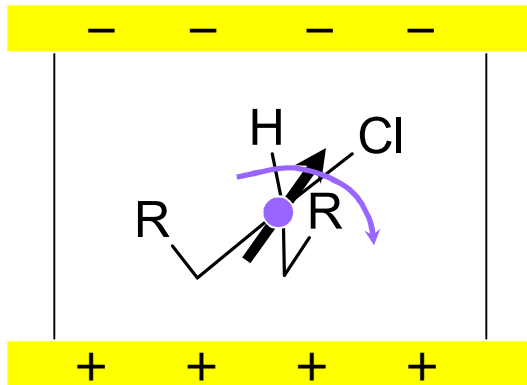
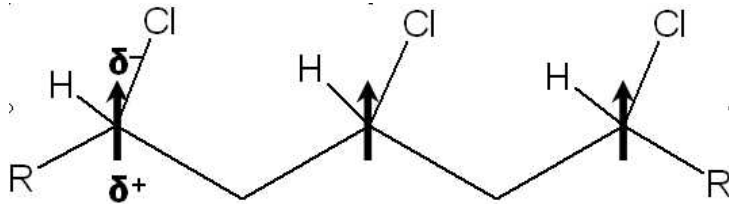
Still room for improvement on the PVDF-based chemistry:

- EAPs of this material are excellent in terms of response time and max strain
(Better than wet EAPs, silicones, conductive doped polymers, piezoelectric ceramics)
- But the voltage requirements are too high (kV/device) and the electrical properties have large T dependence



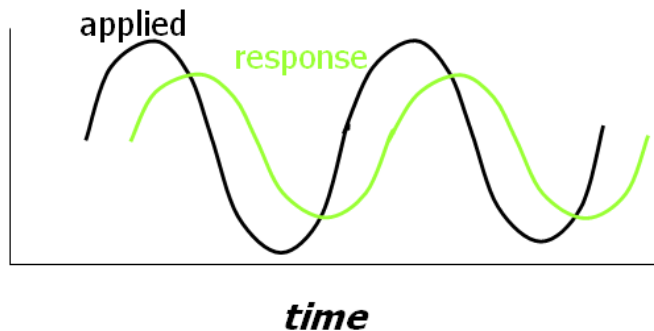
eap.jpl.nasa.gov,
Yoseph Bar-Cohen

Polymer dynamics have important impact on mechanical properties and conductivity



Ability to rotate or translate with field is related to:

- Polymer T_g
- Local (β) relaxations (e.g., in PMMA)
- Ion transport
- Liquid crystal transitions (e.g., smectic to nematic to disordered)

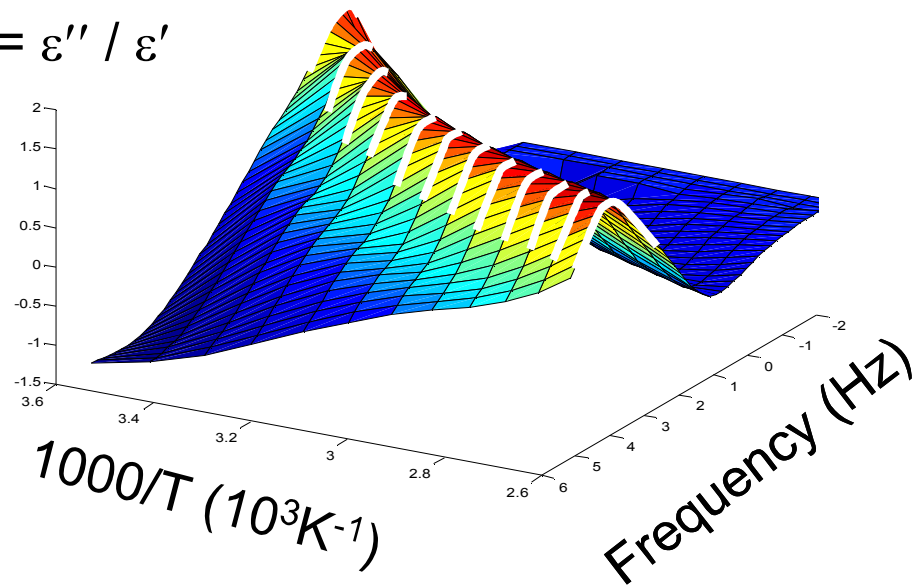


Dynamics in ion-containing polymers: Characterization techniques

Novocontrol broadband dielectric analyzer with temperature controller



$$\tan \delta = \varepsilon'' / \varepsilon'$$

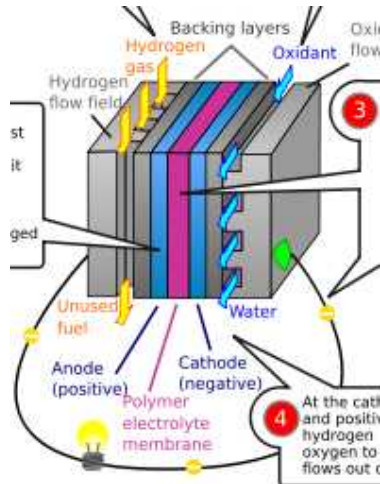


DSC, FTIR, DMA (T_g behavior, coordinated state of oxygen species)

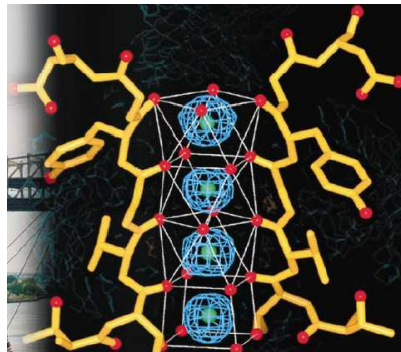
Ion transport is dependent on ion-polymer interactions and polymer dynamics



Battery electrolytes
(secondary Li batteries)



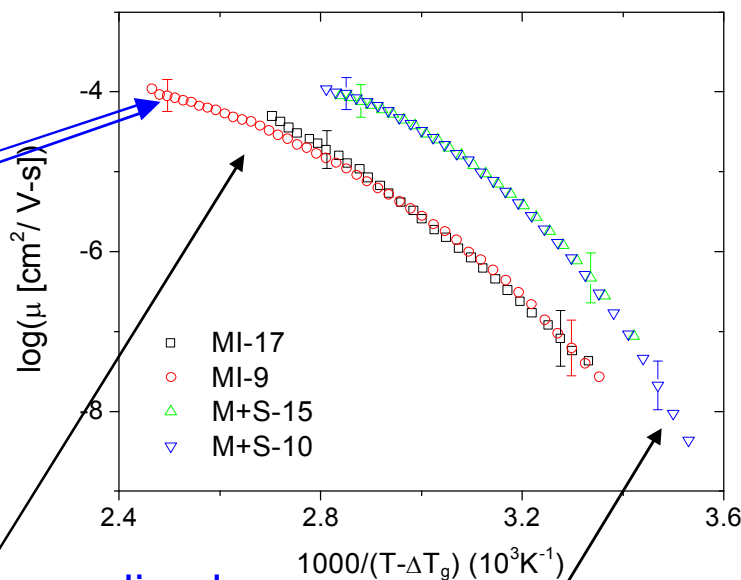
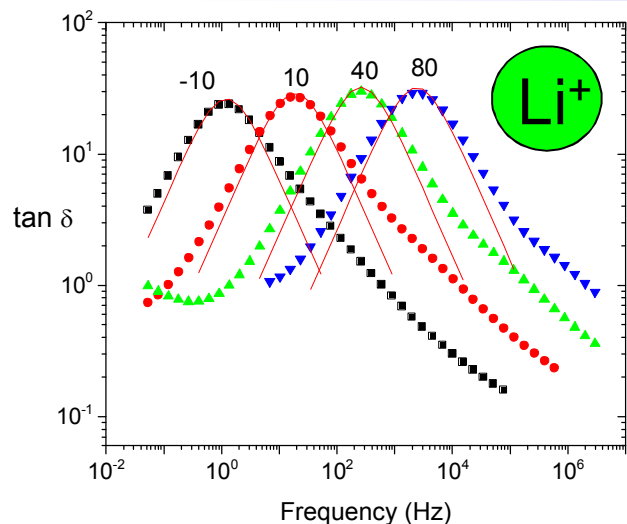
Fuel cell
membranes



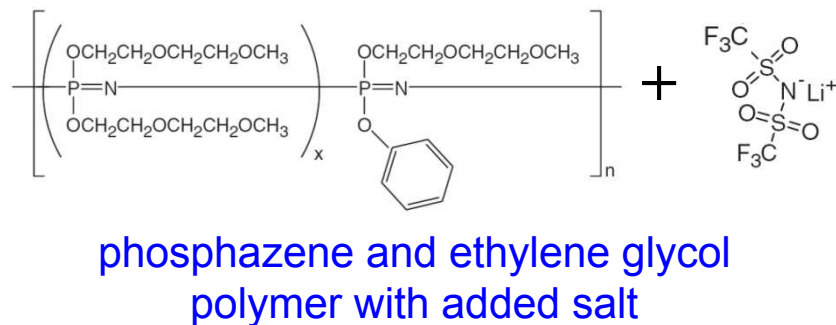
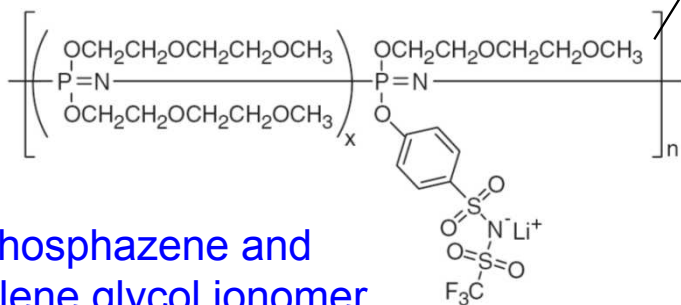
Biological ion
channels

Sources: Wikipedia, Nature v418 p268

Ion and polymer dynamics are typically coupled



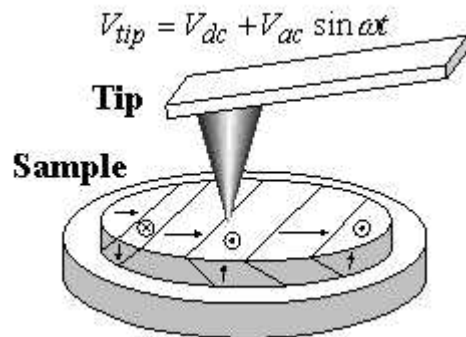
Mobility of ions normalized
by T_g collapse by chemistry



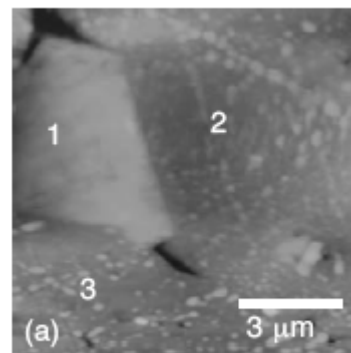
Dielectric spectroscopy of polymers: Future directions

Dielectric spectroscopy will continue to be an important technique for polymers, especially in the membrane and ionic transport fields

In particular, combination of smaller probes (AFM or micro-contacts) with dielectric analyzers will provide key interfacial and surface information

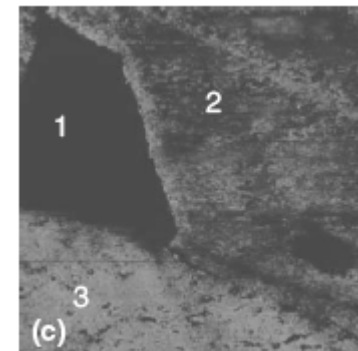


Topography



0nm 60nm

Impedance
phase shift

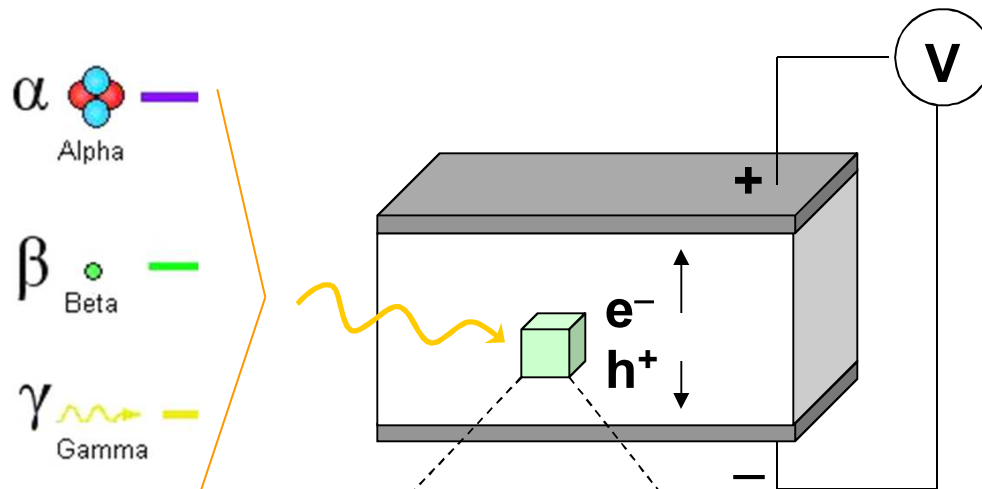


-90° -20°

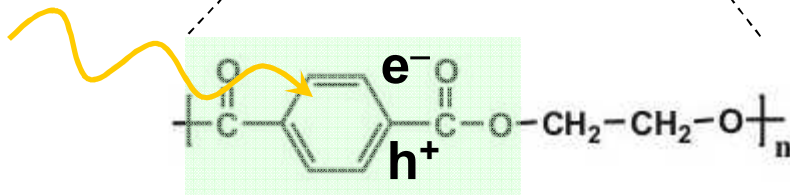
nanotransport.ornl.gov/Research/nanopfm.html,

Shao et al 2004 JJAP

Ionizing radiation degrades dielectric capability by forming electrons and holes



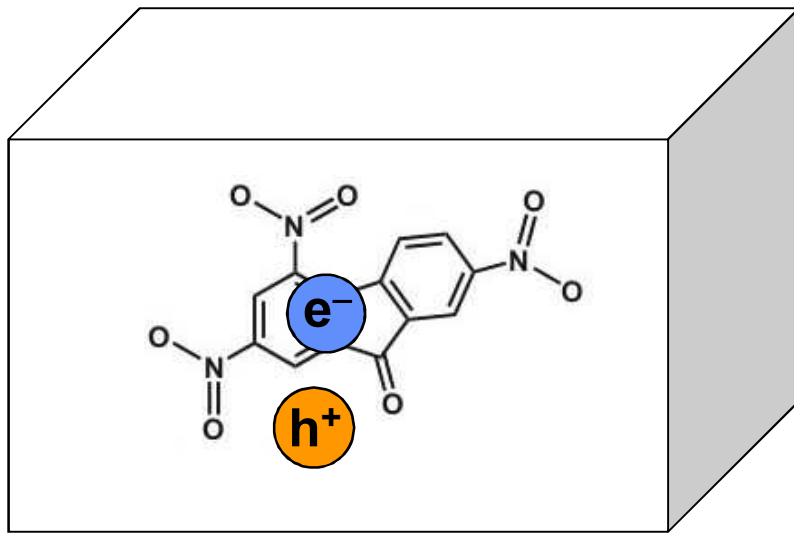
Electric field leads to charge separation, degrading charge storage



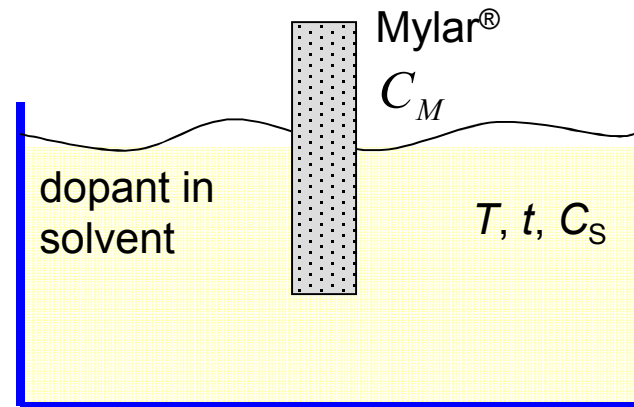
Probable interaction site in poly(ethylene terephthalate)

By adding an electron trap to the polymer,
we reduce RIC to a working level

A deep electron trap reduces RIC by pinning
the electron until it recombines with a hole

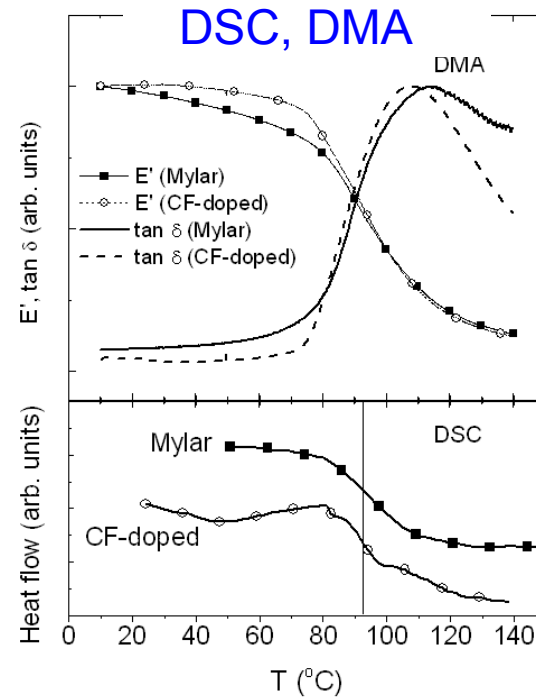
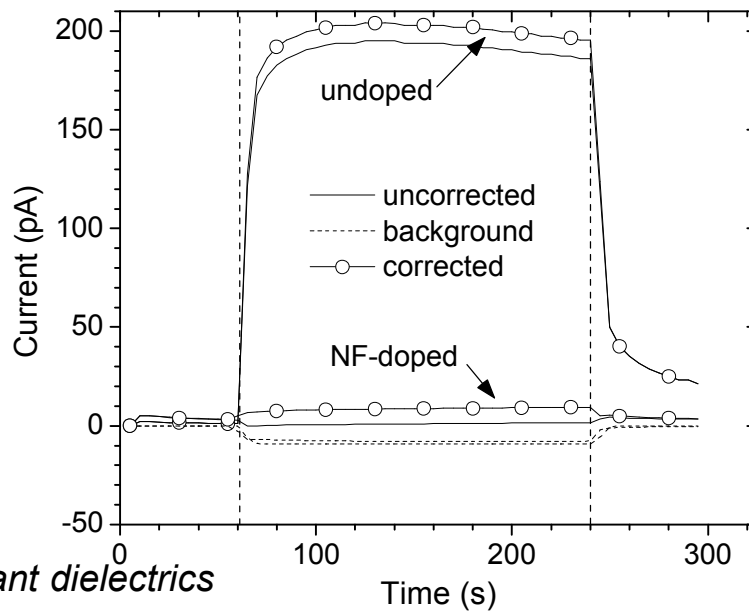
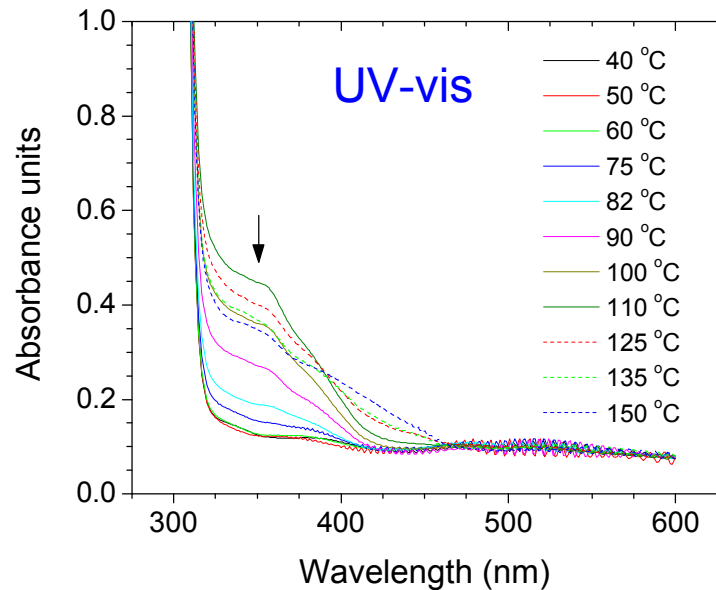


in Mylar film (PET)



We add electron traps by by dissolving dopant in
solvent and immersing film above T_g

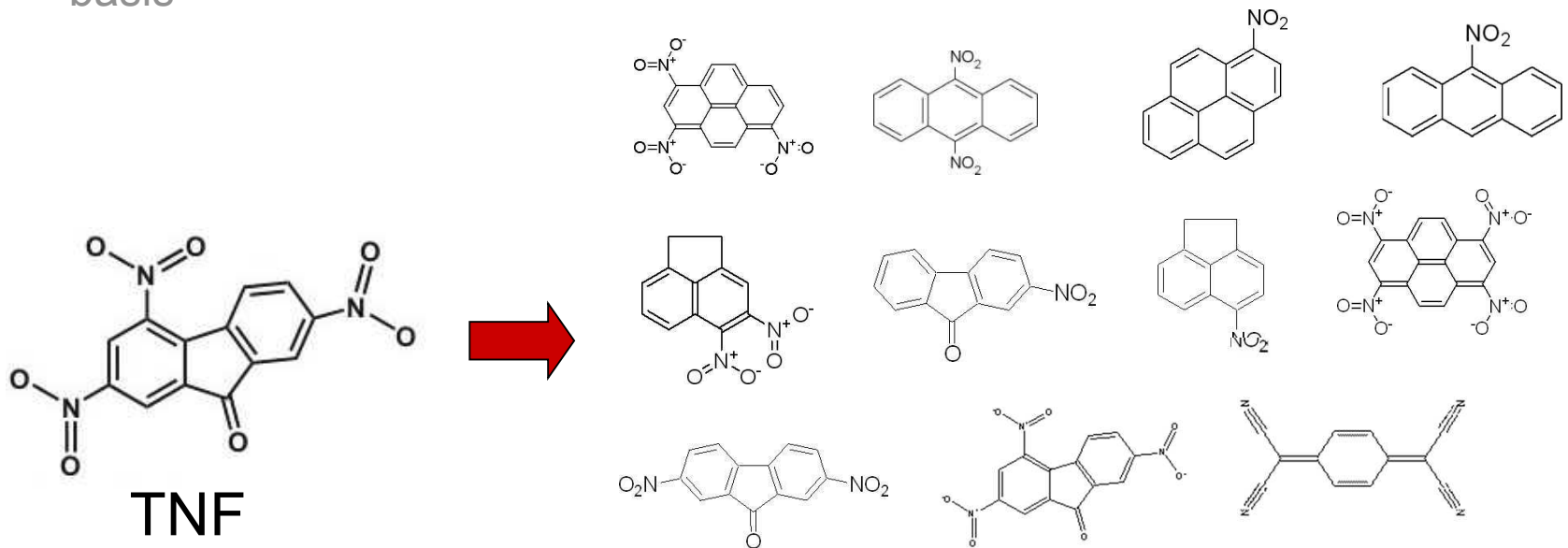
Radiation tolerant dielectrics: Characterization techniques



High flux radiation
sources with electrical
analyzers

Recent work in radiation tolerant dielectrics

- 1) Expanded viable dopant list from 1 to >10
- 2) Constructed pilot plant for processing large batches
- 3) Established dopant chemistry link to radiation tolerance
- 4) Modeled kinetics and thermodynamics of doping process on theoretical basis

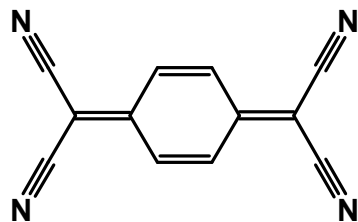


- 1) TNF classified as an explosive in late 1990's and external vendors will no longer use
- 2) Process not optimized and expensive
- 3) Ethylene glycol selected as solvent without clear understanding

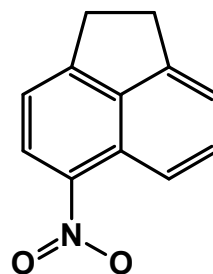
Several small molecules have capability to reduce RIC significantly

Lenhart JAP 2008: 30 rad/s

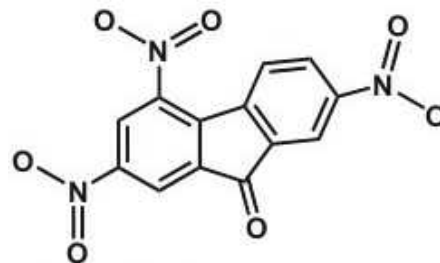
Dopant	Conc. dopant (mol/m ³)	RIC (pA)	RIC reduction (%)
none	0	204	0
TCQM	1.1	29	86
NAN	14	14	93
TNF	50	3.0	98



Tetracyanoquinodimethane
(TCQM)



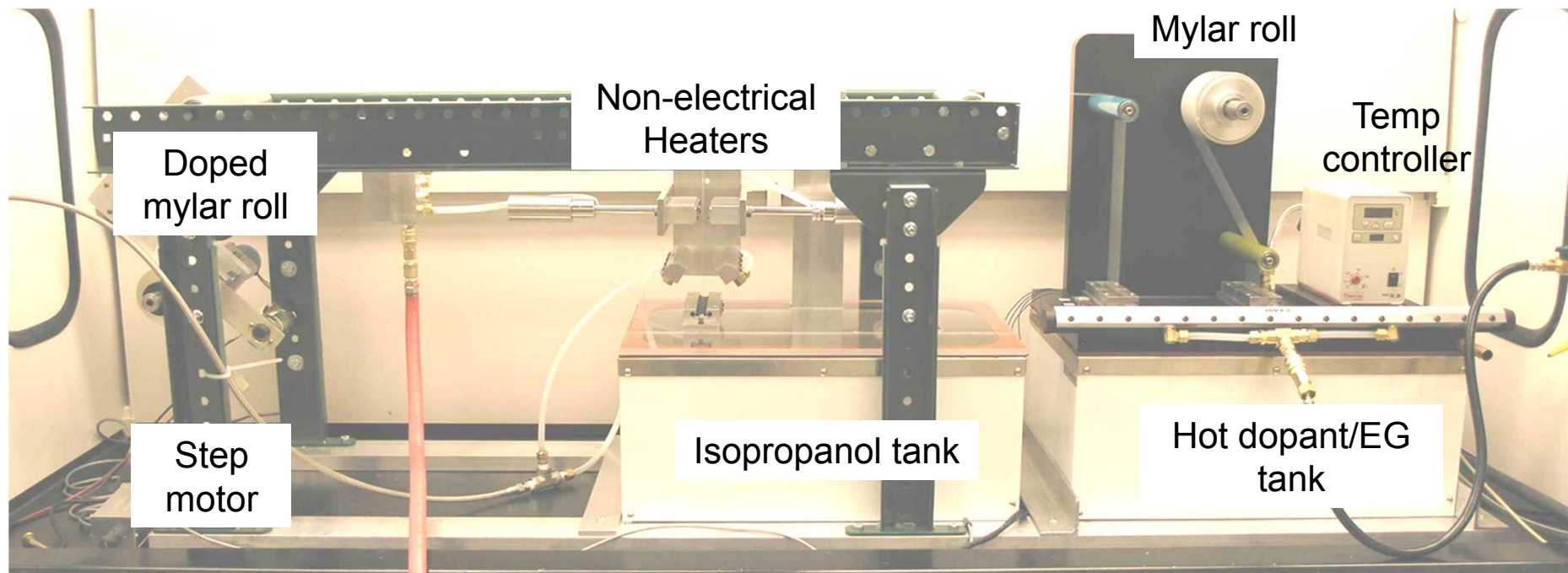
Nitroacenaphthene
(NAN)



Trinitrofluorenone
(TNF)

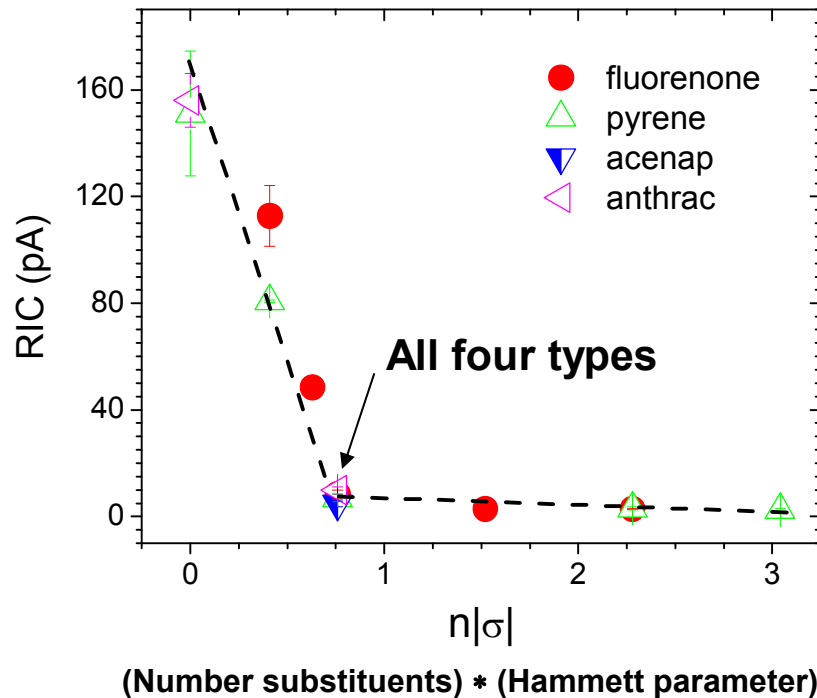
Recent work in radiation tolerant dielectrics

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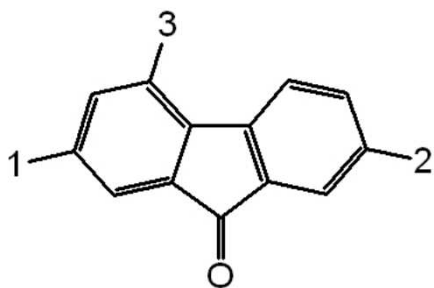
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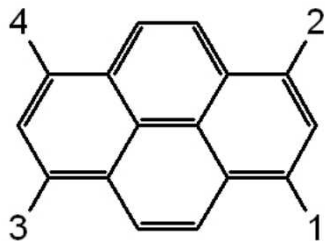


*Predictive model for
impact of substituent*

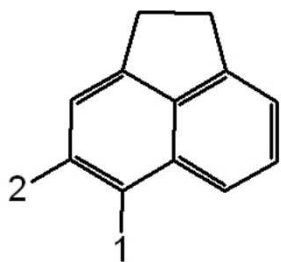
We selected dopants with conjugated
cores and electron-withdrawing groups



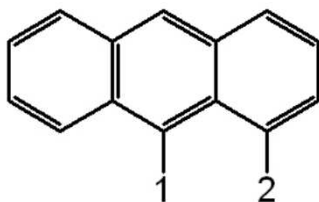
Fluorenone (F)



Pyrene (P)

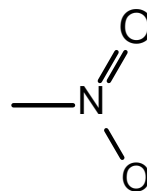


Acenaphthene (Ac)

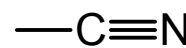


Anthracene (Ant)

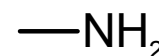
Numbered positions may
represent:



Nitro

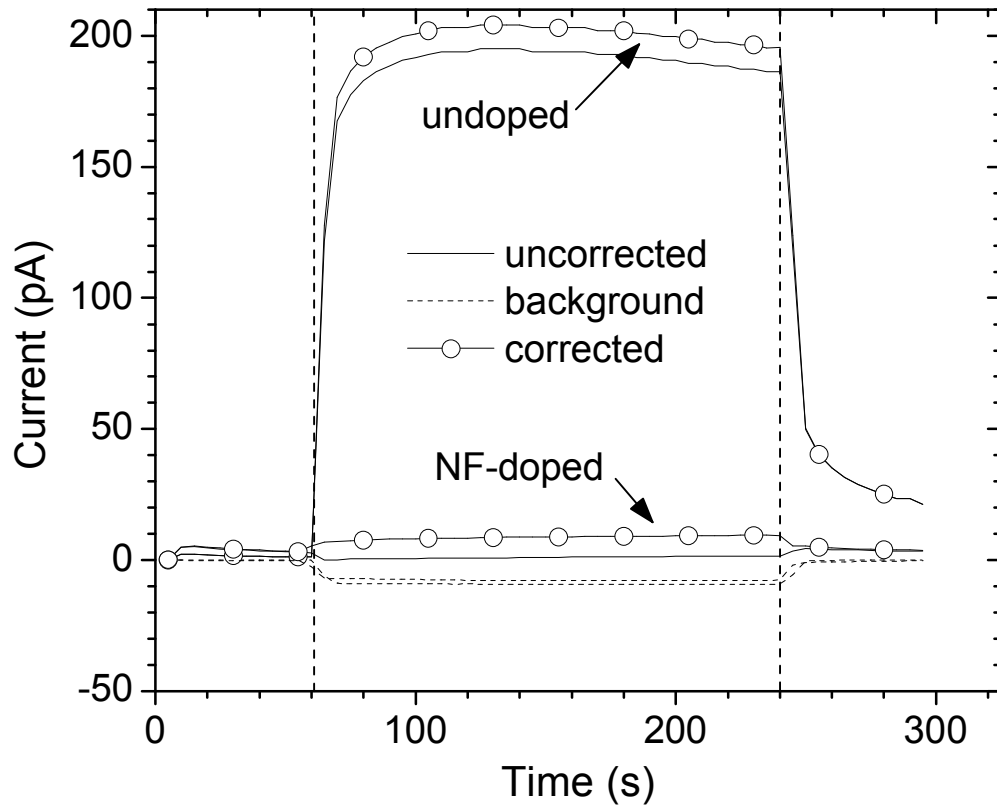


Cyano



Amino

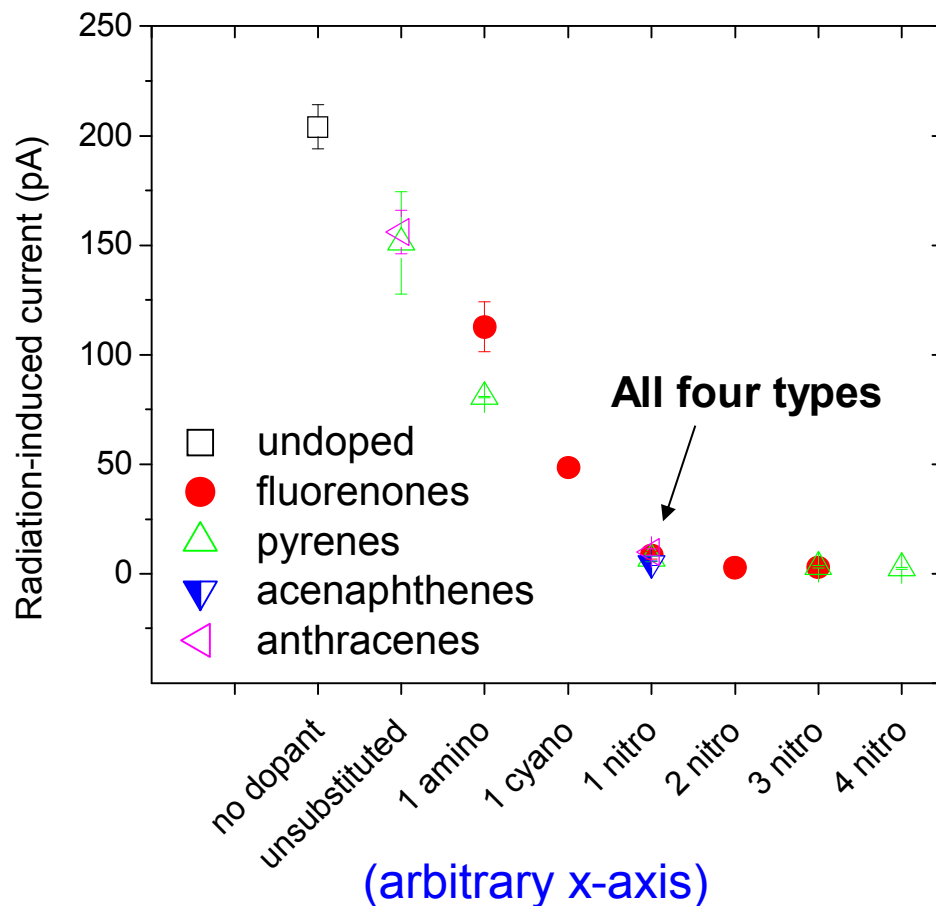
RIC is evaluated as the plateau in $I(t)$



Uncorrected = 29 V/ μm

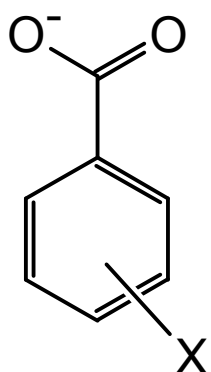
Background = 0 V (slightly negative due to radiation interacting with wires and epoxy)

Trend in RIC emerges as a function of substituted group



Electron-withdrawing ability of substituent roughly correlates with lowered RIC, *for all conjugated cores*

RIC behavior can be (semi)-quantified by Hammett parameter



Evaluated by Hammett for variously substituted benzoic acid:
 e^- withdrawing substituent stabilizes acidity*

$$\sigma_X = \log \frac{K_X}{K_H}$$

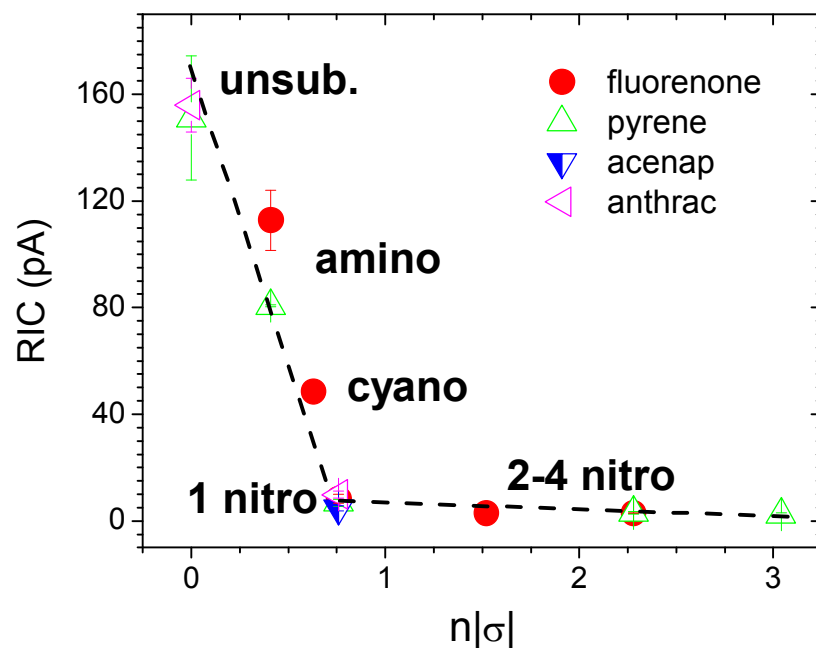
Substituent	σ_{para}	σ_{meta}
-------------	-----------------	-----------------

$-\text{NO}_2$	0.77	0.74
----------------	------	------

$-\text{C}\equiv\text{N}$	0.65	0.61
---------------------------	------	------

$-\text{NH}_2$	-0.63	-0.21
----------------	-------	-------

$-\text{H}$	0	0
-------------	---	---



Establishes *predictive*
model for impact of
substituent

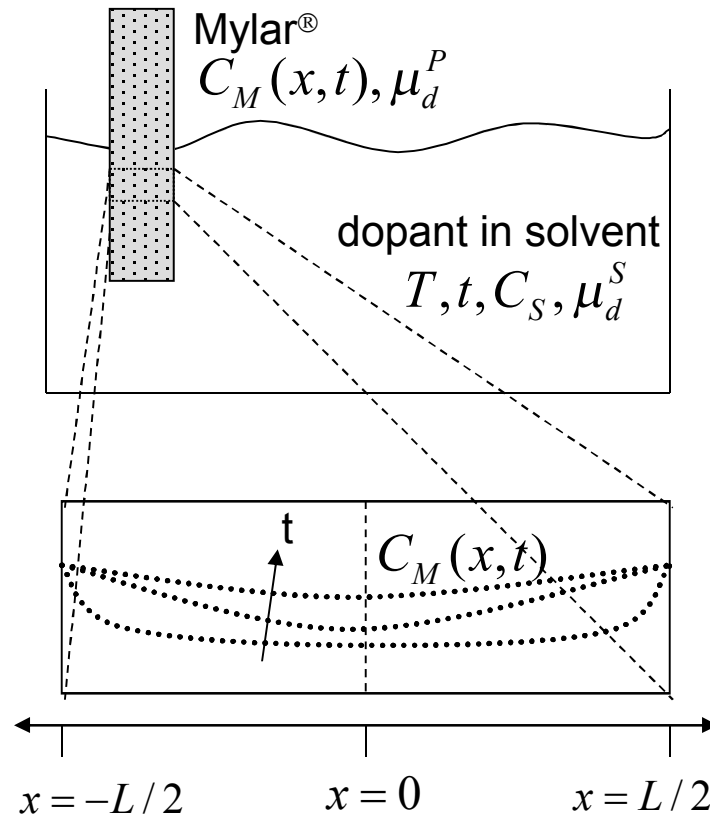
* A. Pross, *Theoretical and Physical Principles of Organic Reactivity*, 1995

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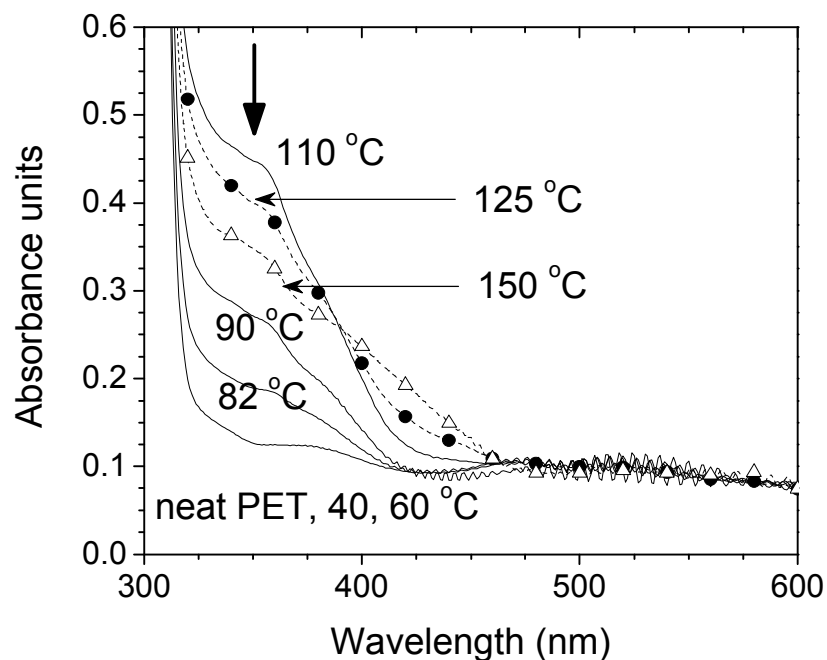
Dopant concentration
evaluated by UV-vis

And fit with model to obtain
physical parameters

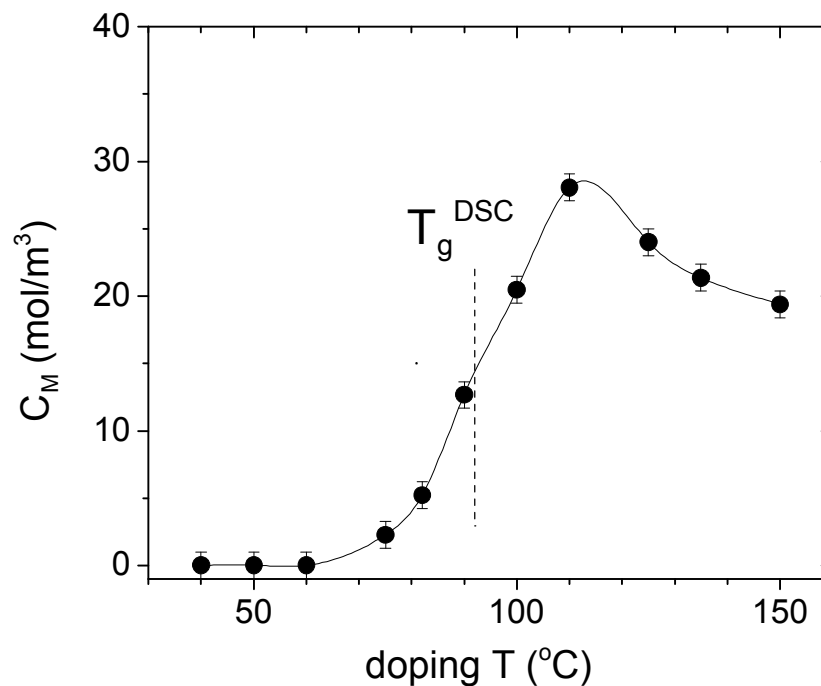



Diffusion efficient only above polymer T_g

Baselined UV-vis spectra
of TNF-doped PET



Corresponding C_M (after 20 h)
as a function of T





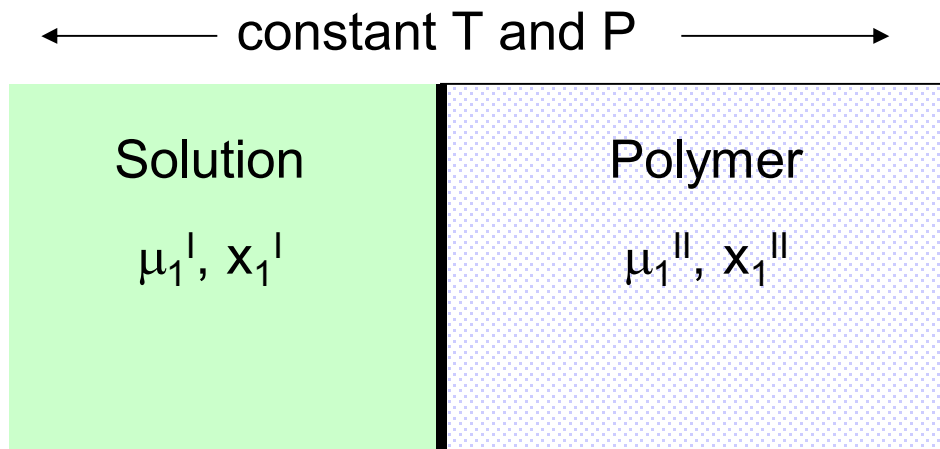
Partition coefficient (thermodynamics) can be predicted from chemical potential theory

Fugacities of component partitioned between two phases provides K based on activity coefficients

In order to predict K we need estimates for the activity coefficients!

Ultimately, we found a combination of theories worked to predict behavior:

- 1) Flory-Huggins
- 2) χ parameters predicted from solubility parameters
- 3) Solubility parameters from experiment or group contribution theory
- 4) Additional term to account for H-bonding in solution

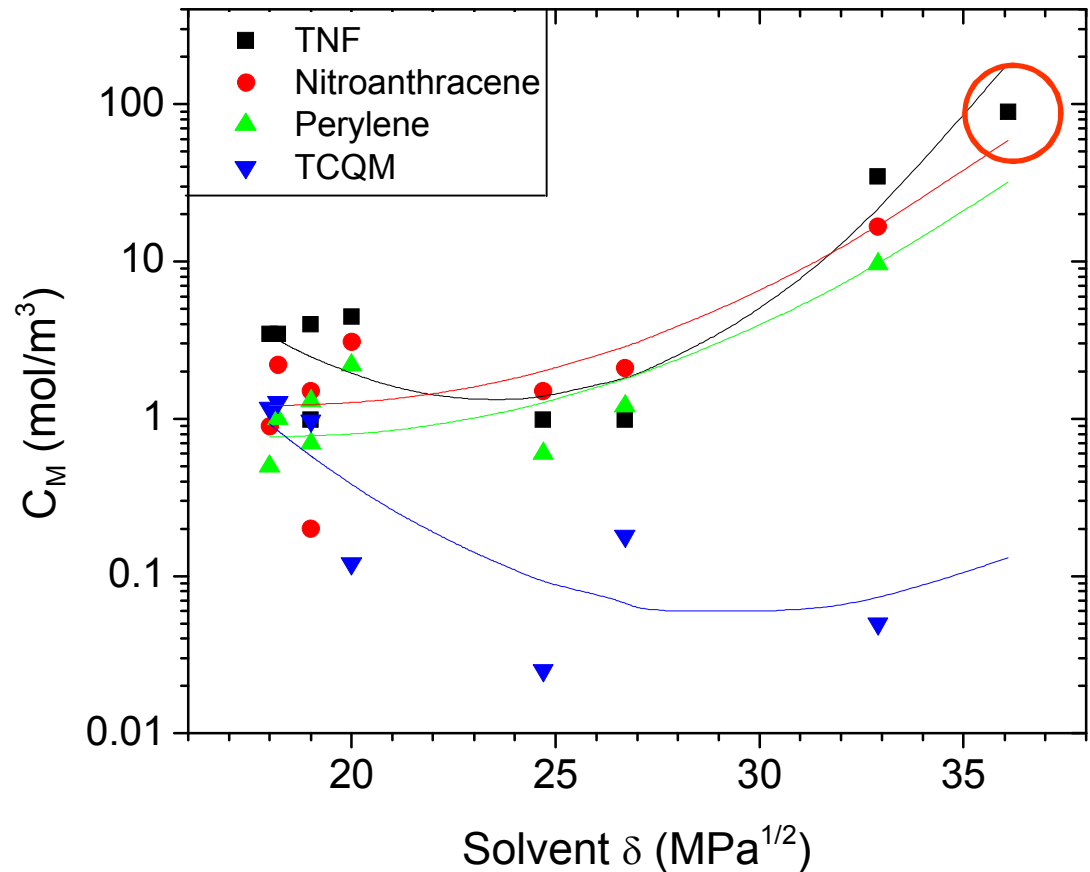


Experimental data for wide variety of dopants and solvents linked to theory

$$C_M = a_1 \exp \left\{ b_1 \left[v_m^{d,S} (\delta_S - \delta_d)^2 - v_m^{d,P} (\delta_P - \delta_d)^2 \right] \right\}$$

Very strong correlations
between solvent
solubility parameter
and final C_M

Glycerol predicted to be
better than EG for TNF,
and this is confirmed by
experiment

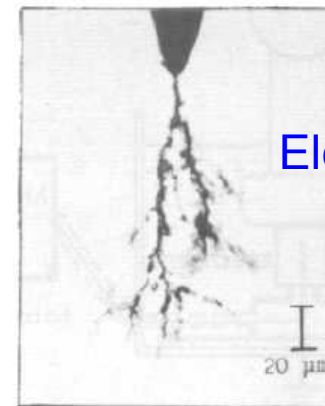
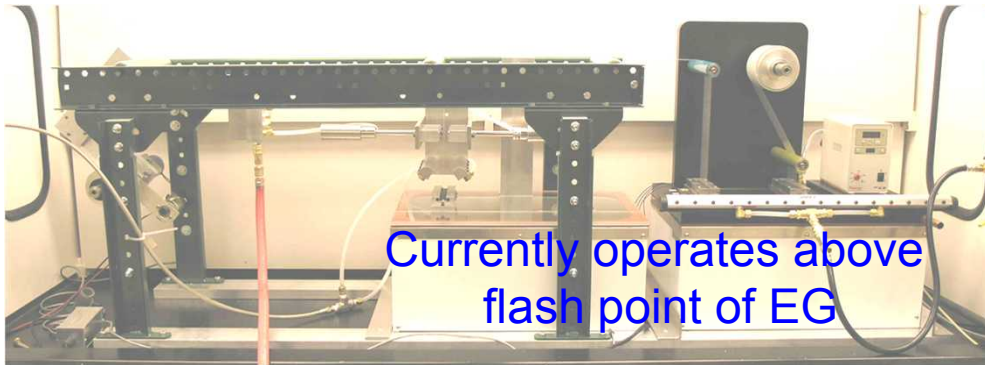


Radiation tolerant dielectrics: Future directions

Improvements to process already underway
(lower cost materials, safer and more dependable process)

Electron traps at high conc lower the breakdown voltage by acting as defect sites. Based on breakdown theory in insulators, holes should have the opposite effect

So we are pursuing doping with hole traps to increase breakdown voltage in Mylar as well as in filled systems



Electrochemical
treeing

Pulfrey 1972
J Phys D

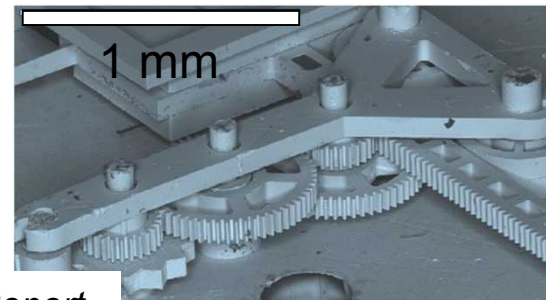
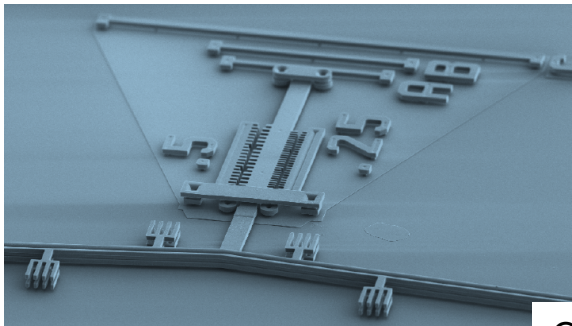
SAMs for anti-stiction of MEMS

Motivation: Class III and IV MEMS devices (impacting/rubbing surfaces)

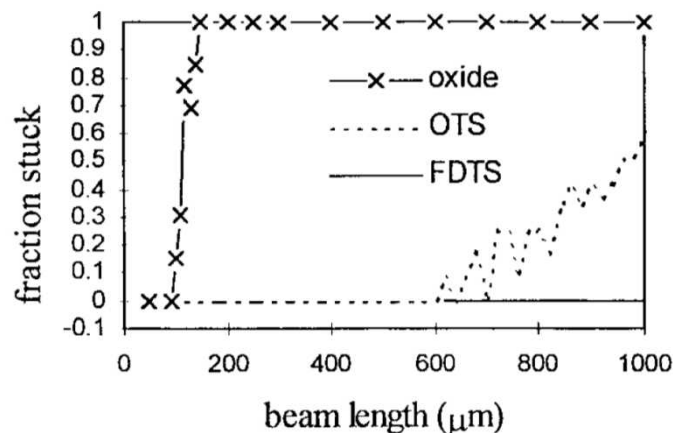
Untreated MEMS last for 10^2 to 10^3 cycles

MEMS with single-layer SAMs last for 10^4 to 10^5 cycles

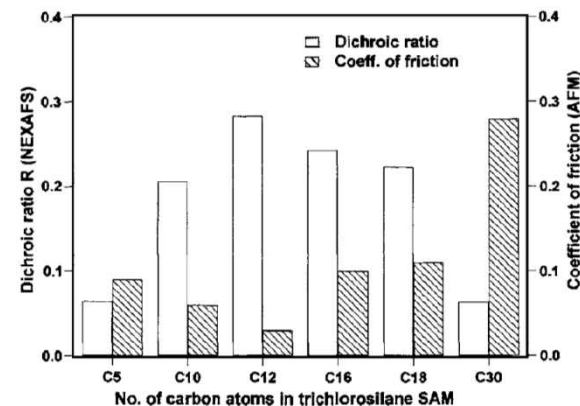
Reliable devices require 10^6 to 10^8 cycles



Oliver 2002 *Sand Report*



Srinivasan 1998 *J MEMS*

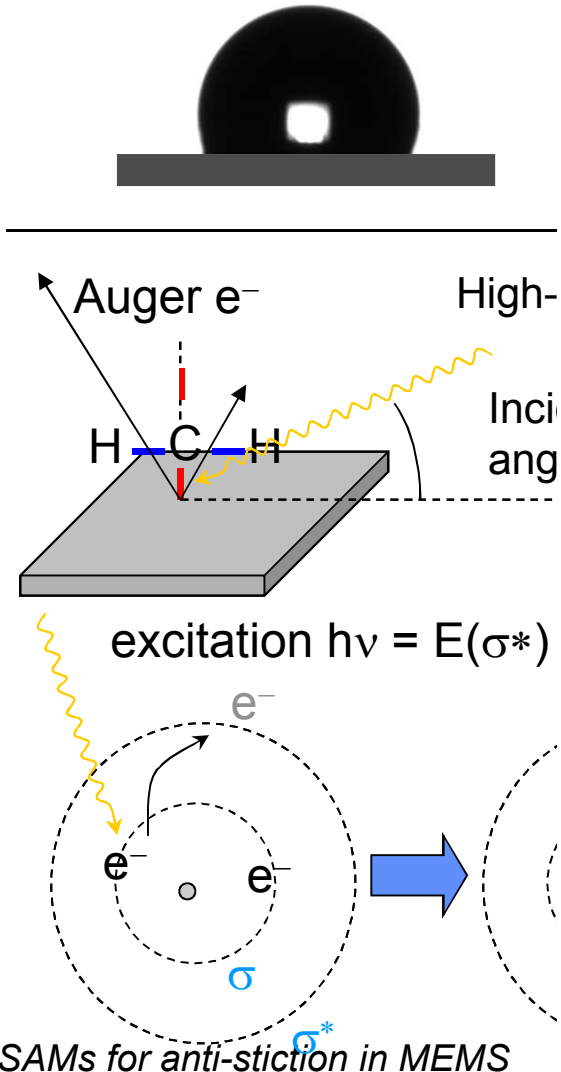


Sambasivan 2006 *J Vac Sci Tech A*

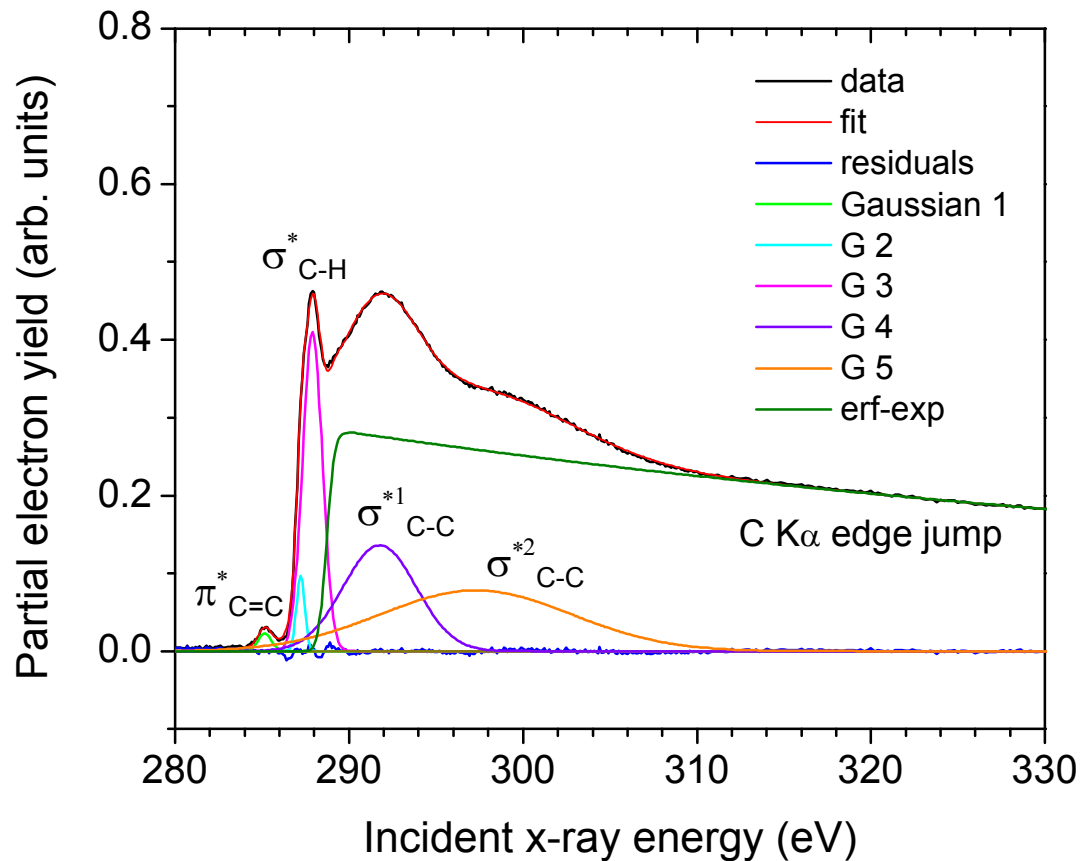
SAMs for anti-stiction in MEMS:

Characterization techniques

Sessile/advancing/receding
goniometry



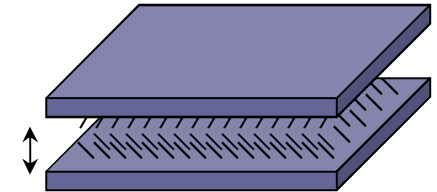
Near edge x-ray absorption
fine structure (NEXAFS)



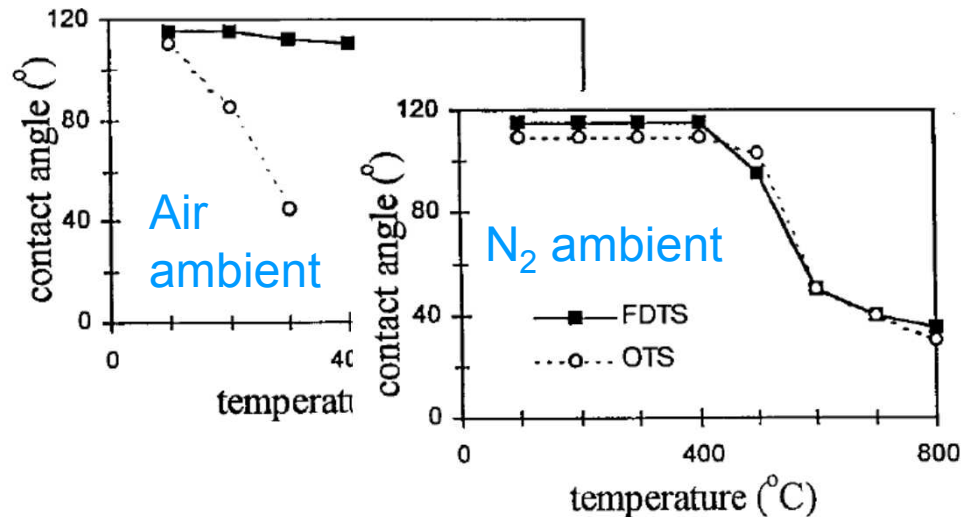
SAM wear leads to device failure

3 routes envisioned to SAM failure

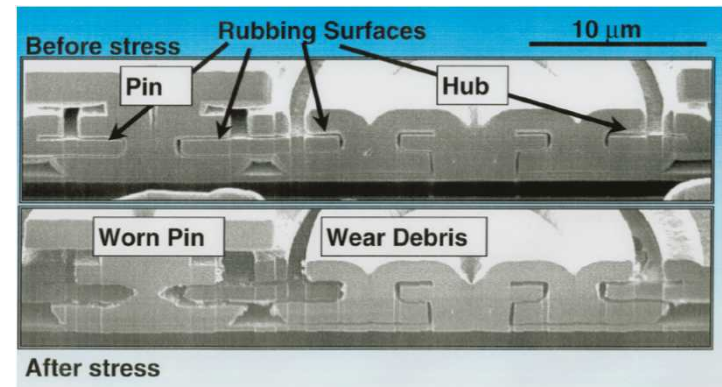
- Wear leads to local heating, cleaving C-C bonds
- Wear scratches silicon surface and 'uproots' SAMs
- Mechanical heating and humidity hydrolyzes Si-O-Si bonds



~2 nm separation
between surfaces

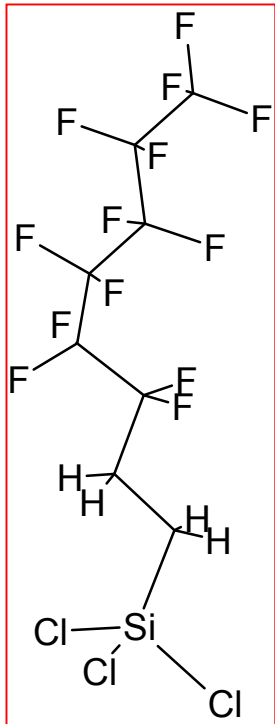










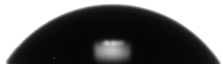

Srinivasan 1998 *J MEMS*



Jenkins 2004 *Sand Report*

Comparison of degradation mechanisms



	<u>Heat treated</u>	<u>Worn</u>	
350 °C			10 s
375 °C			30 s
400 °C			60 s
425 °C			120 s
450 °C			240 s
	(1 h heating under air atmosphere)	(1-d rubbing, 2 FOTS surfaces, 1 Hz, 1 kg force)	

Contact angle measurements show basic trend;
NEXAFS provided fundamental chemical changes

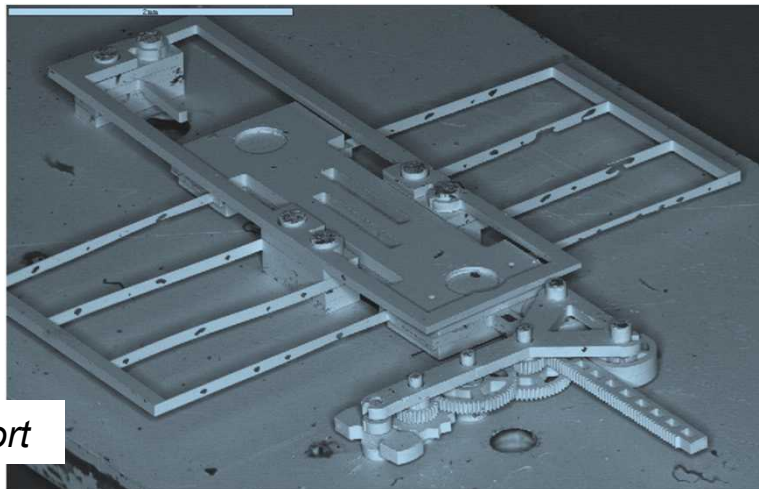
SAMs for anti-stiction in MEMS: Future directions

Fluorinated trichlorosilanes, although ideal for fundamental study, are not sufficient for use in MEMS with rubbing surfaces

However, we have evidence that certain chemistries form a regenerating, non-covalent, protective layer*

If a source is hermetically sealed into a MEMS device, lifetime is extended to tens of millions of cycles. NEXAFS will be used to characterize the wear mechanisms

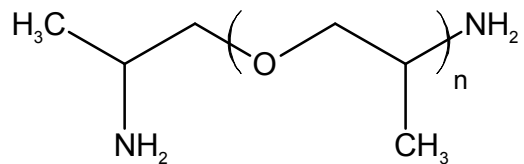
*Collaboration with
Mike Dugger at Sandia



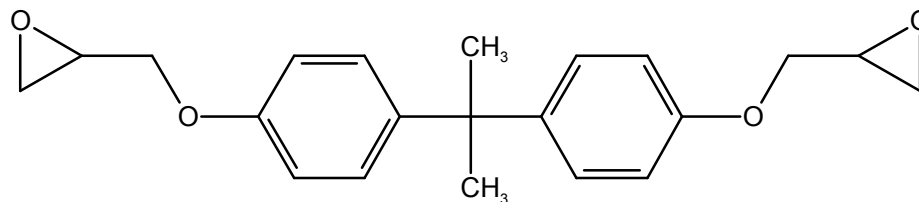
Oliver 2002 *Sand Report*

A sacrificial filler with a catalyst for the epoxide chemistry produces controlled pore sizes

Matrix: epoxide and amine

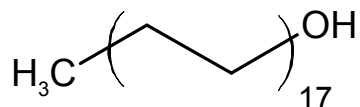


D230



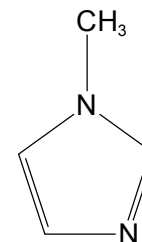
BADGE

Filler



1-octadecanol

Catalyst

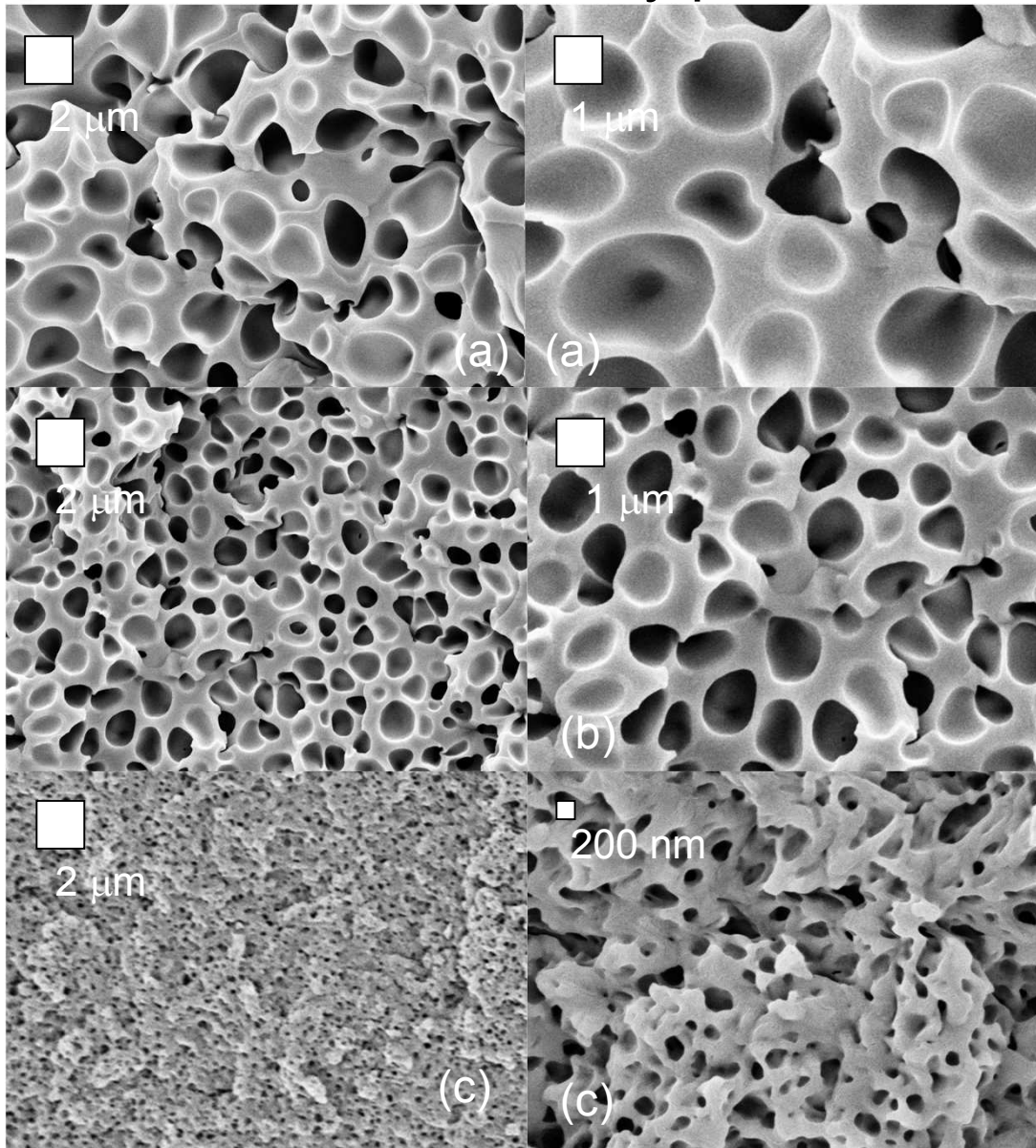


1-methylimidazole

Characterization techniques:

SEM, 3-point fracture test (ASTM)

A sacrificial filler with a catalyst for the epoxide chemistry produces controlled pore sizes



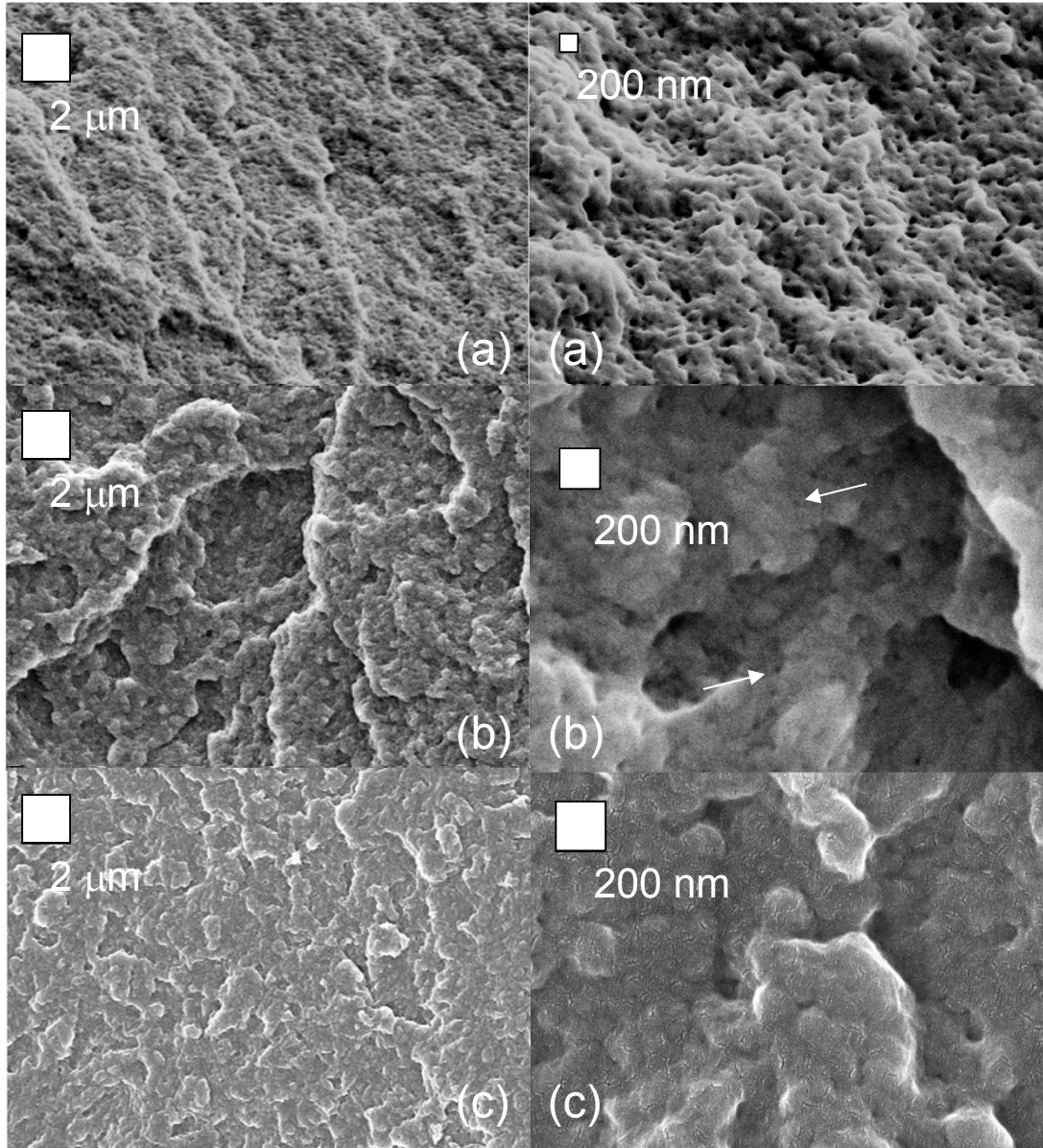
90 °C cure, 40 wt% octadecanol

0.3 wt% imidazole

0.4 wt% imidazole

0.5 wt% imidazole

A sacrificial filler with a catalyst for the epoxide chemistry produces controlled pore sizes



90 °C cure, 40 wt% octadecanol

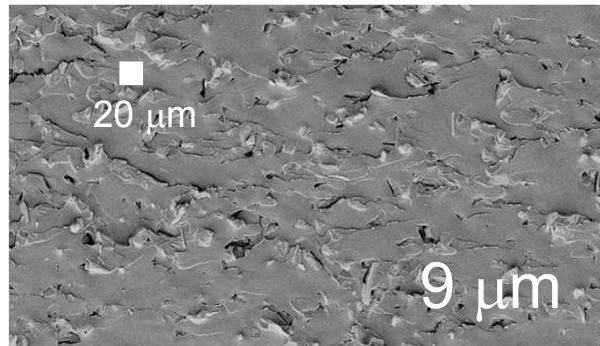
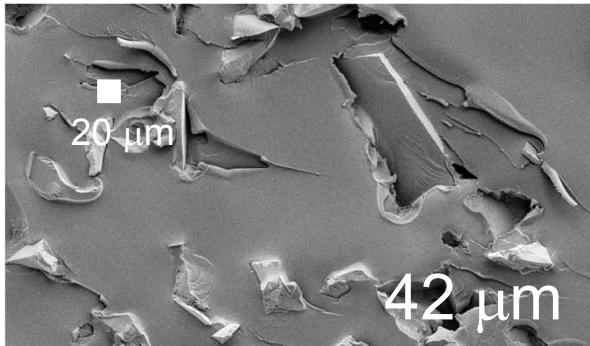
0.6 wt% imidazole

0.8 wt% imidazole

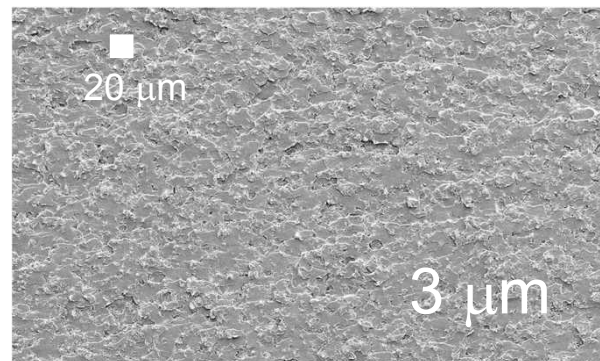
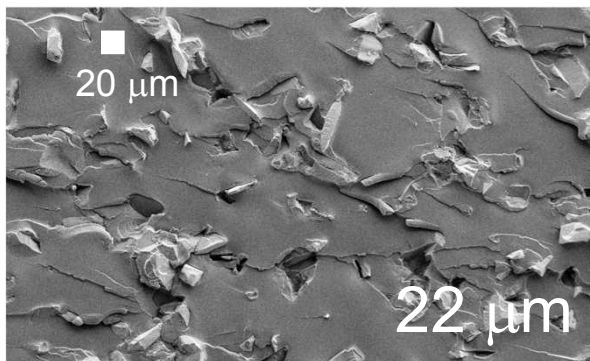
0.9 wt% imidazole

Alumina filler increases ε , E_Y , and K_{IC} , and decreases CTE;
any benefit to smaller particles or coupling agents?

Fracture direction →

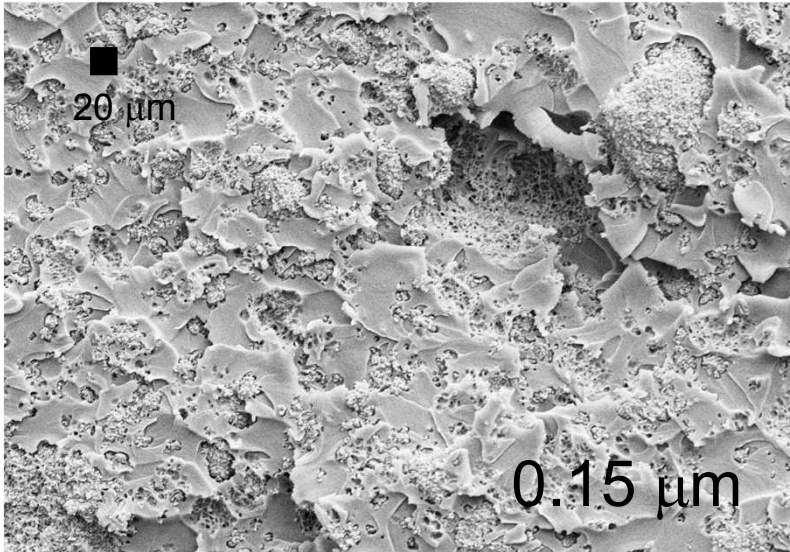


Well-dispersed
particles

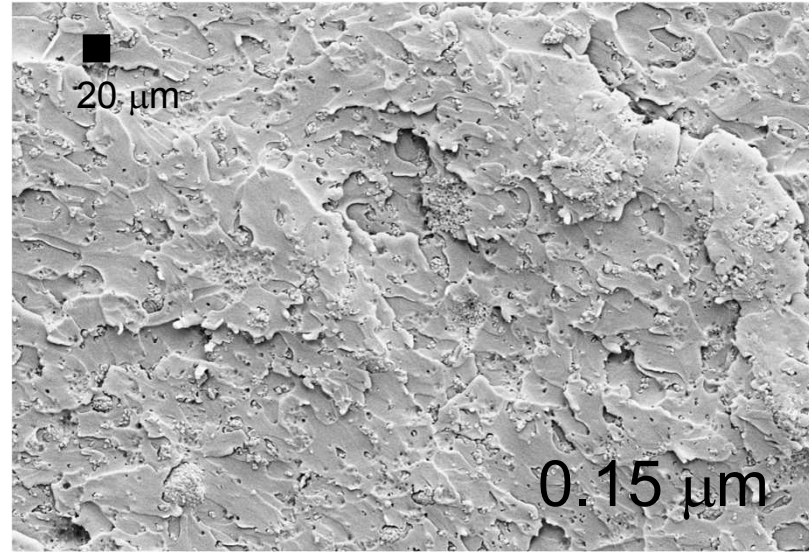


Fracture surface gets
rougher with smaller
particles

Alumina filler increases ε , E_Y , and K_{IC} , and decreases CTE;
any benefit to smaller particles or coupling agents?



Untreated, dispersed with sonic horn
and mechanical mixer

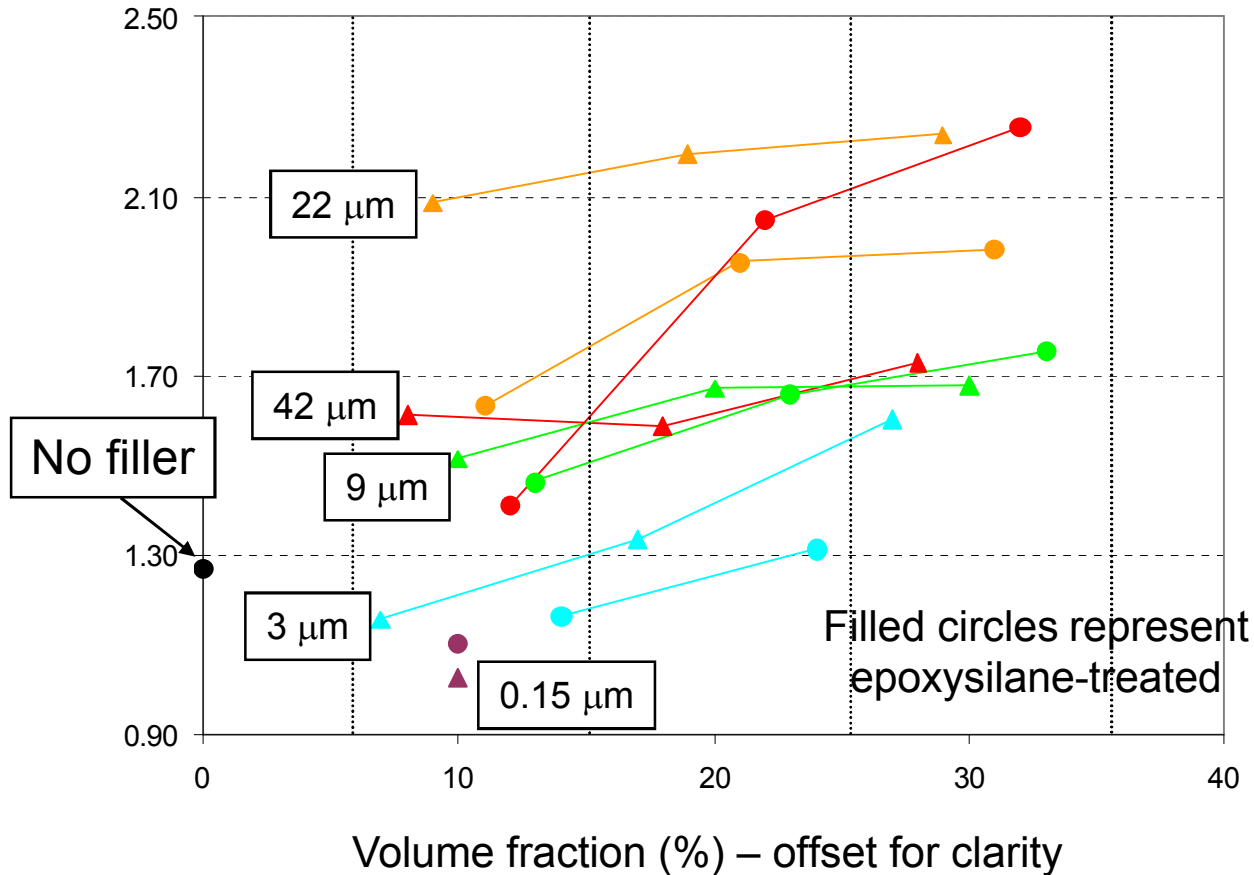


Treated with epoxyhexyltrichlorosilane,
dispersed with sonic horn and
mechanical mixer

Surface treated particles lead to better dispersion

Alumina filler increases ε , E_Y , and K_{IC} , and decreases CTE;
any benefit to smaller particles or coupling agents?

Fracture toughness K_{IC} (Mpa m^{1/2})



K_{IC} is not improved
by nanofillers or
silane coupling agent

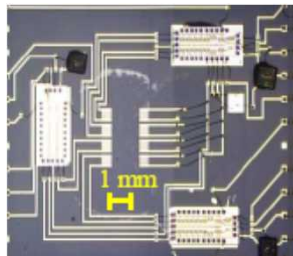
Porous and filled epoxies: Future directions

Filled epoxies: provide a baseline for the impact of particle size on processing (viscosity) and mechanical properties (fracture toughness)

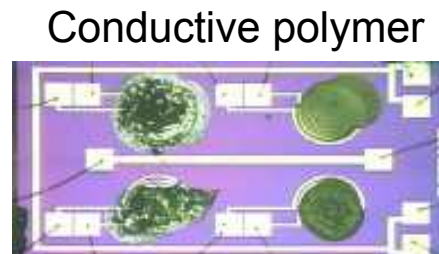
A better understanding of rheological percolation and crack deflection as a function of size will lead to better design parameters

We can also try to design coupling agents to decrease viscosity while increasing particle-polymer interactions in the solid state

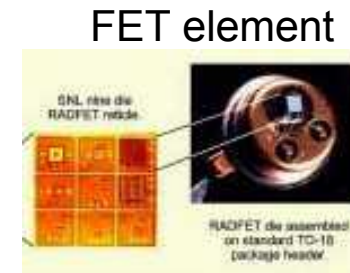
Porous epoxies: besides traditional applications at Sandia, also very important for chemical sensors



SAWs with gel



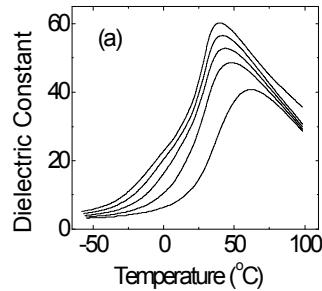
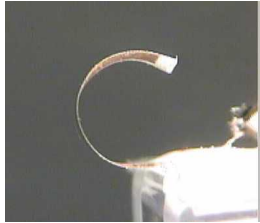
Conductive polymer



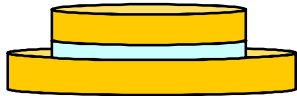
FET element

Various sensors from Sandia – Ho
2004 Sand Report

Highlights of my past and present research in organic materials

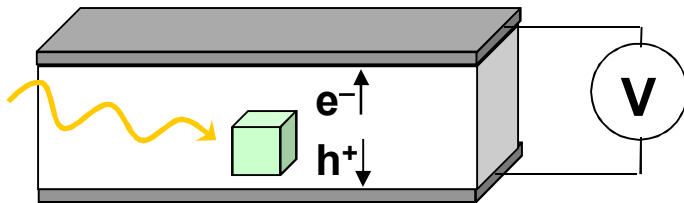


PVDF-based terpolymers for electroactive transducers and high ϵ capacitors

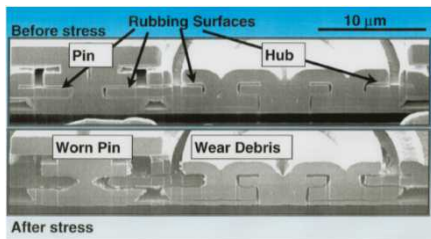


$$\epsilon^*(f, T)$$

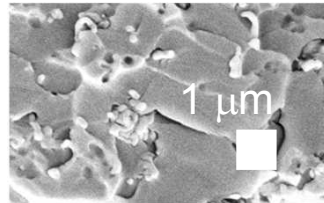
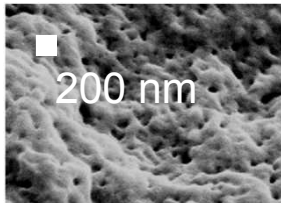
Polymer and ion dynamics in ionomers and polymer electrolytes



Radiation tolerance in polymer dielectrics*



Self-assembled monolayers for anti-stiction in MEMS



Polymer composites: porous and alumina filled epoxies



Luna Innovations seminar

August 18 2008

Robert Klein

Graduate and postdoctoral work

PENNSSTATE



DEPARTMENT OF
MATERIALS
SCIENCE AND
ENGINEERING

COLLEGE OF EARTH AND
MINERAL SCIENCES

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Mike Lanagan, Feng Xia,
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Schroeder, Shana Cole,
Mike Belcher, Mark Stavig



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Cherno Jaye, Zugen Fu

University of California, Santa Barbara
CHEMICAL ENGINEERING

(undergraduate)

***Advisors**

Sandia is a multiprogram laboratory operated by Sandia Corporation, a Lockheed Martin Company, for the United States Department of Energy's National Nuclear Security Administration under contract DE-AC04-94AL85000



First author papers (1)

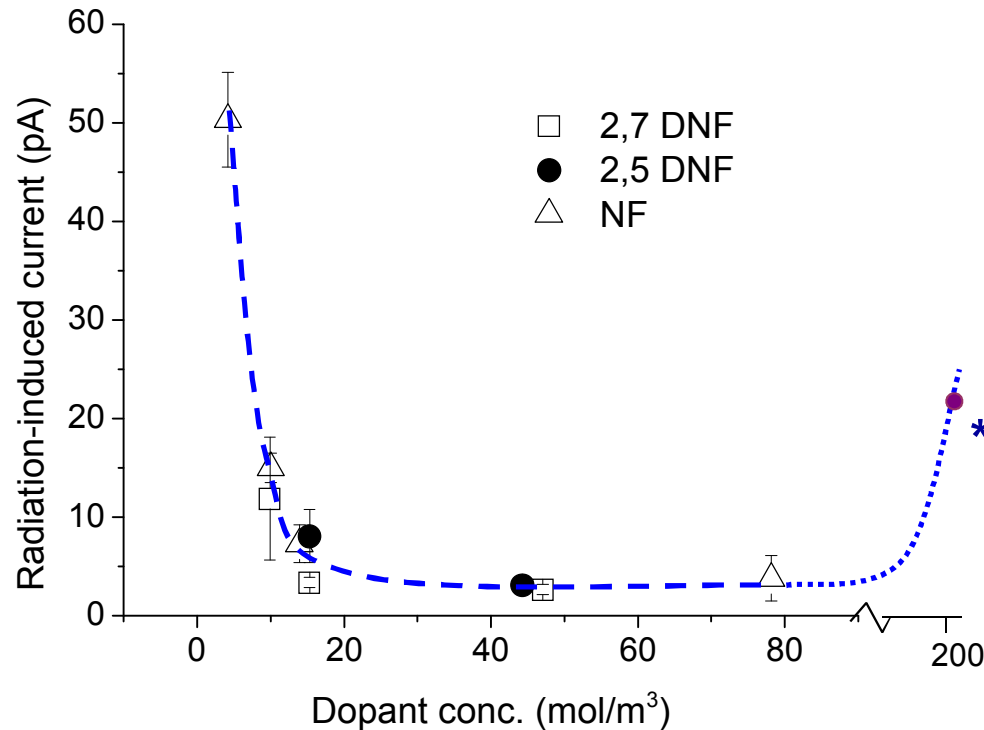
- 1) Systematic wear and heat treatment of self-assembled monolayers for anti-stiction, characterized by near edge x-ray absorption fine structure and contact angle
RJ Klein, DA Fischer, JL Lenhart, *in preparation*
- 2) Porous epoxies by phase separation of removable alcohols: control of spherical pore size by mass fraction, cure temperature, and reaction rate
RJ Klein, MC Celina, and JL Lenhart, *submitted to Chemistry of Materials*
- 3) Radiation tolerance in polymeric dielectrics by small-molecule doping I: Dopant uptake as a function of temperature, time, and chemistry
RJ Klein, SM Cole, ME Belcher, JL Schroeder, PJ Cole, JL Lenhart, *submitted to Polymer*
- 4) Radiation tolerance in polymeric dielectrics by small-molecule doping II: Thermodynamic and kinetic parameters
RJ Klein, SM Cole, ME Belcher, JL Schroeder, PJ Cole, JL Lenhart, *submitted to Polymer*
- 5) Systematic oxidation of polystyrene by ultraviolet-ozone, characterized by near edge x-ray absorption fine structure and contact angle
RJ Klein, Daniel A. Fischer, JL Lenhart, *Langmuir* **2008** 24 8187
- 6) Reduction of radiation-induced conductivity in poly(ethylene terephthalate): Effect of dopant structure
RJ Klein, JL Schroeder, SM Cole, ME Belcher, PJ Cole, JL Lenhart, *Polymer* **2008** 49 2632



First author papers (2)

- 7) Plasticized Single-Ion Polymer Conductors: Conductivity, Local and Segmental Dynamics, and Interaction Parameters
RJ Klein, J Runt, *Journal of Physical Chemistry B* **2007** 111 13188
- 8) Counterion effects on ion mobility and mobile ion concentration of doped polyphosphazene and polyphosphazene ionomers
RJ Klein, DT Welna, AL Weikel, HR Allcock, J Runt, *Macromolecules* **2007** 40 3990
- 9) Modeling electrode polarization in dielectric spectroscopy: ion mobility and mobile ion concentration of single-ion polymer electrolytes
RJ Klein, SH Zhang, SC Dou, BH Jones, RH Colby, J Runt, *Journal of Chemical Physics* **2006** 124 144903-1
- 10) Influence of composition on relaxor ferroelectric and electromechanical properties of poly(vinylidene fluoride-trifluoroethylene-chlorofluoroethylene)
RJ Klein, F Xia, QM Zhang, F Bauer, *Journal of Applied Physics* **2005** 97 094105
- 11) Influence of crystallization conditions on the microstructure and electromechanical properties of poly(vinylidene fluoride-trifluoroethylene-chlorofluoroethylene) terpolymers
RJ Klein, J Runt, QM Zhang, *Macromolecules* **2003** 36 7220
- 12) Producing super-hydrophobic surfaces with nano-silica spheres,
RJ Klein, RM Biesheuvel, BC Yu, CD Meinhart, FF Lange, *Zeitschrift fur Metallkunde* **2003** 94 377

Within a wide range, dopant concentration has little effect on RIC



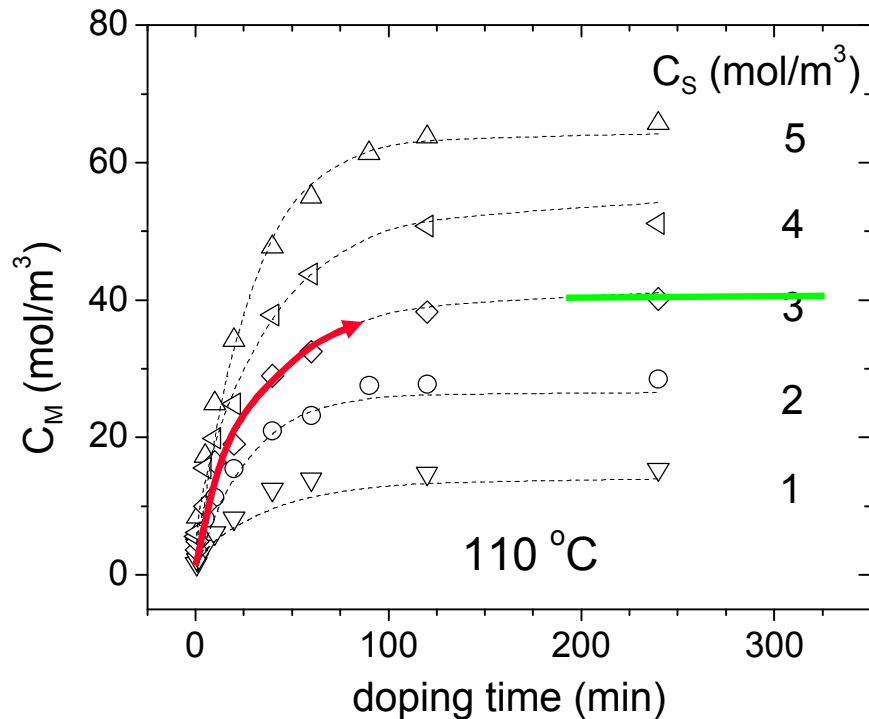
This plateau is typical of all dopants

Stable from 10 mol/m³ ($6 \times 10^{18} \text{ cm}^{-3}$) to <200 mol/m³ ($1 \times 10^{20} \text{ cm}^{-3}$)

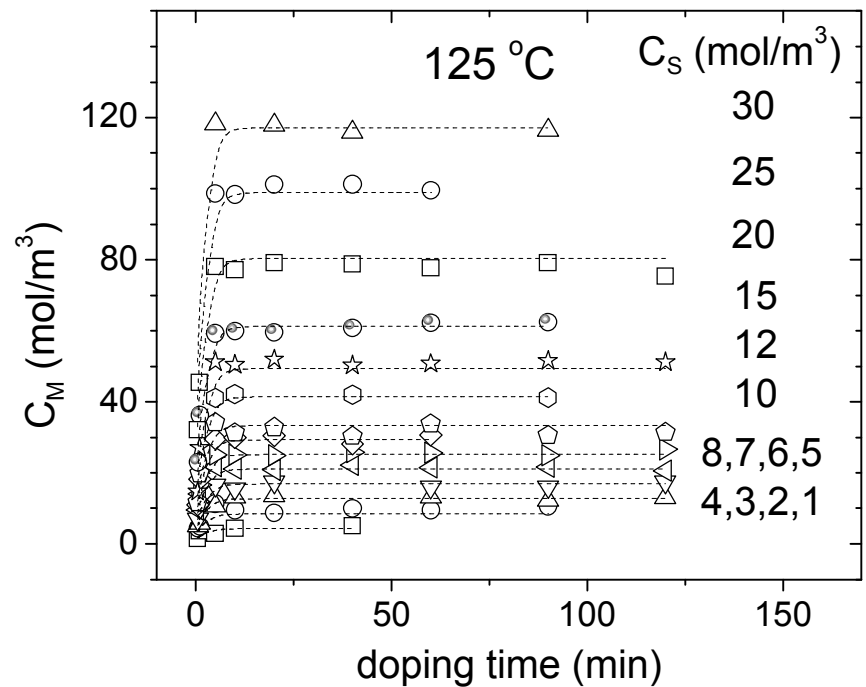
* TNF, from Kurtz *IEEE Trans Nucl Sci* 1983

Model fits rise and plateau in $C_m(t)$ very well

TNF at 110 °C



NF at 125 °C



Kinetics follow simple Fickian diffusion through an amorphous solid

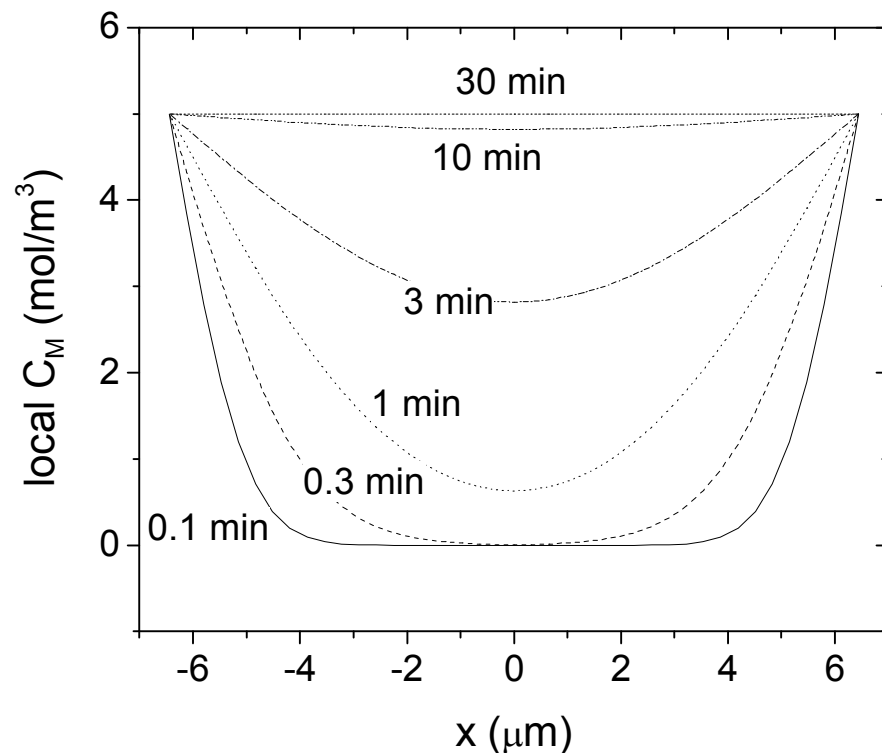
$$D \frac{\partial^2 C_M}{\partial x^2} = \frac{\partial C_M}{\partial t}$$

$$C_M(x, t) = C_M^{eq} \left\{ 1 - 2 \sum_{n=0}^{\infty} \frac{(-1)^n}{(n + 1/2) \pi} \exp \left[- (n + 1/2)^2 \pi^2 \frac{Dt}{(L/2)^2} \right] \cos \left[(n + 1/2) \pi \frac{x}{L/2} \right] \right\}$$

$C_M(t)$ data modeled with
single parameter D
(diffusivity)

*Due to crystallinity actual
diffusivity is higher than
observed by

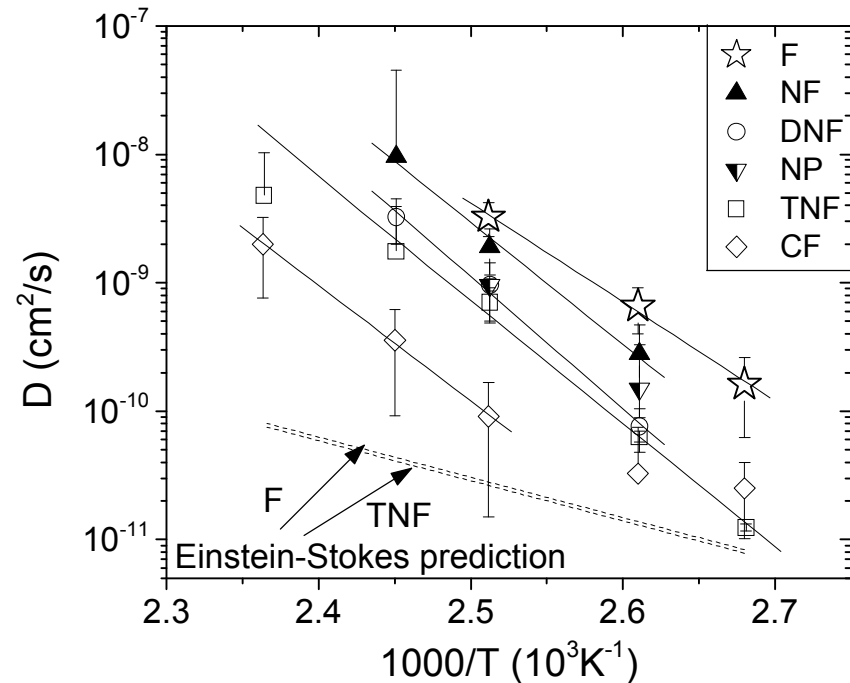
$$D = \frac{D_A \phi}{\tau}$$



Diffusion of small molecules slowed by the addition of functional groups

Molecular size (volume), which often plays the major role in diffusion^{1,2}, is insignificant

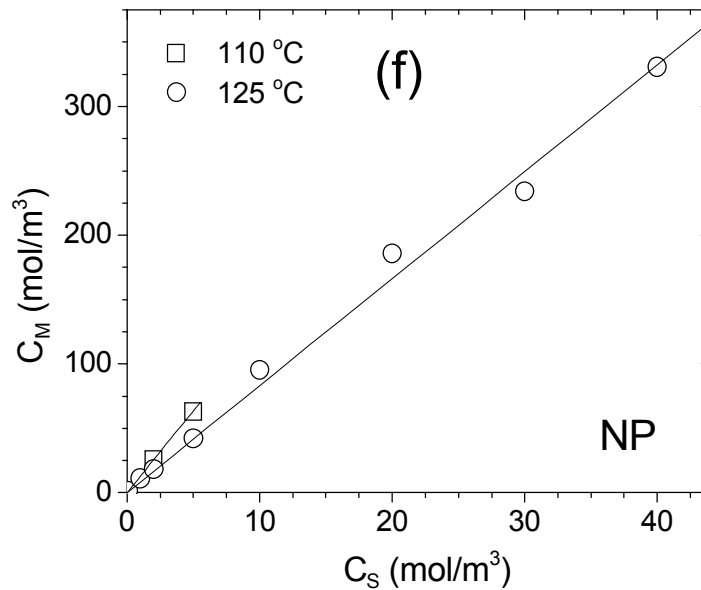
Ordering of dopants is instead based on retarding influence of functional groups

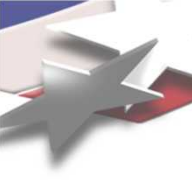


Thermodynamics of partitioning are more complex

First-glance model proceeds by Henry's law approach

$$C_M^{eq} = K_C C_S$$





Initial Mylar® doping process developed in 70's and 80's at SNL, and commercial batches produced

- Edwards¹ surveyed PVDF, Mylar® (PET), and polysulfone
- Kurtz, Arnold, and Hughes² continued work and selected PET for dielectric properties and low water uptake; found RIC reduced 99% with doping TNF from benzyl alcohol³
- Courtalds Performance Films (Virginia) produced TNF-doped Mylar® in 50,000 sq. ft. batches⁴ (late 1980's to 1993)

Problems at the time:

- 1) TNF classified as an explosive in late 1990's and external vendors will no longer use
- 2) Process not optimized and expensive
- 3) Ethylene glycol selected as solvent without clear understanding

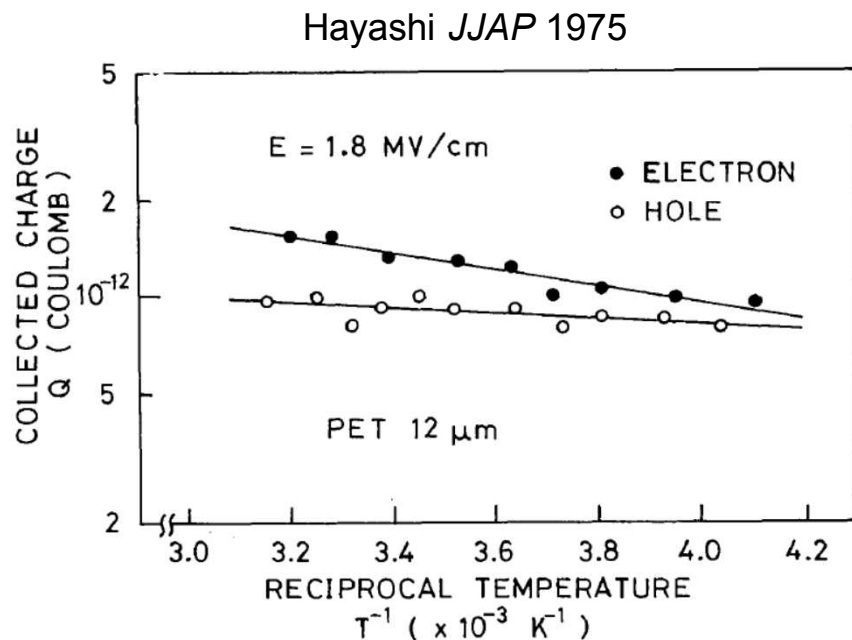
¹L.R. Edwards, *Sandia Report* 1981 SAND-81-0667C

²S.R. Kurtz, R.C. Hughes, *JAP* 1983 54 p229-237

³S.R. Kurtz, C. Arnold, R.C. Hughes, *IEEE Trans Nucl Sci* 1983 30 4077-4080

⁴G.C. Bischoff, L.R. Edwards, *Sandia Report* 1990 SAND-90-2362C

Reduction by amino group may arise from hole trapping

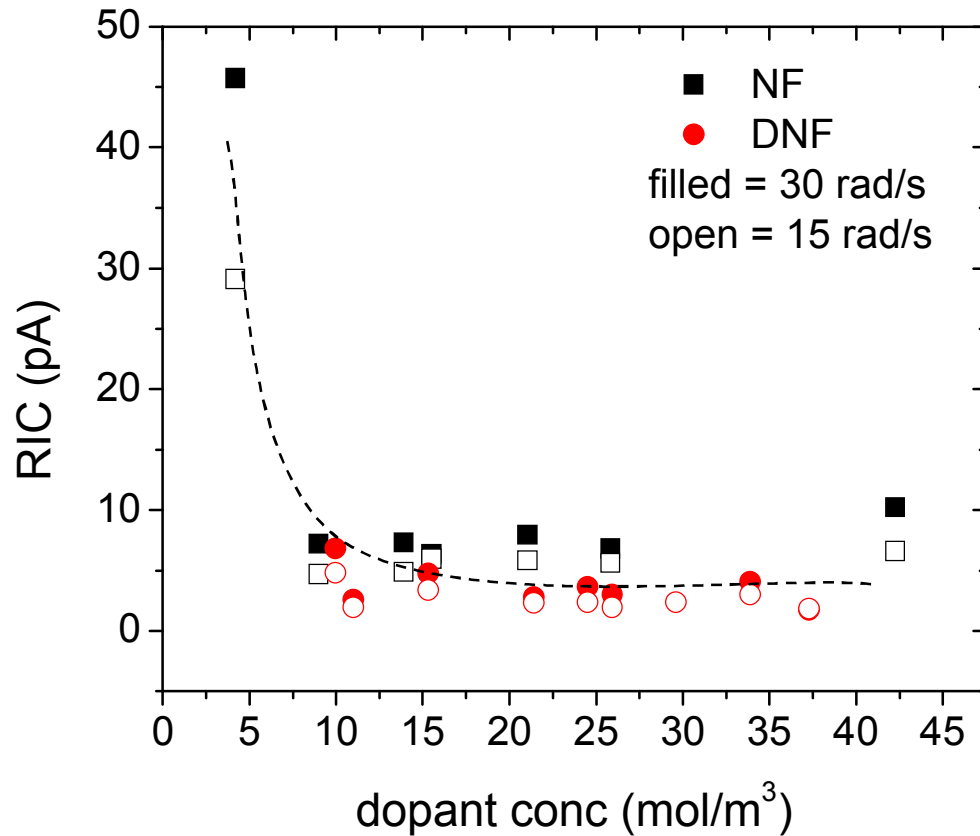


Electron transport dominates* in PET (lifetimes are much longer), but trapping of holes also important

* Hayashi *JJAP* 1975 (pulsed electron beam bombardment, measured as charge collected over time of flight)

* Kurtz *JAP* 1985, Khatipov *High Energy Chem* 2001, Tyutnev *High Energy Chem* 2006

RIC as function of dopant concentration



- 10 to 40 mol/m³ provides 95 to 98 % reduction in RIC



Best method we found was Flory-Huggins model with additional term for H-bond interactions

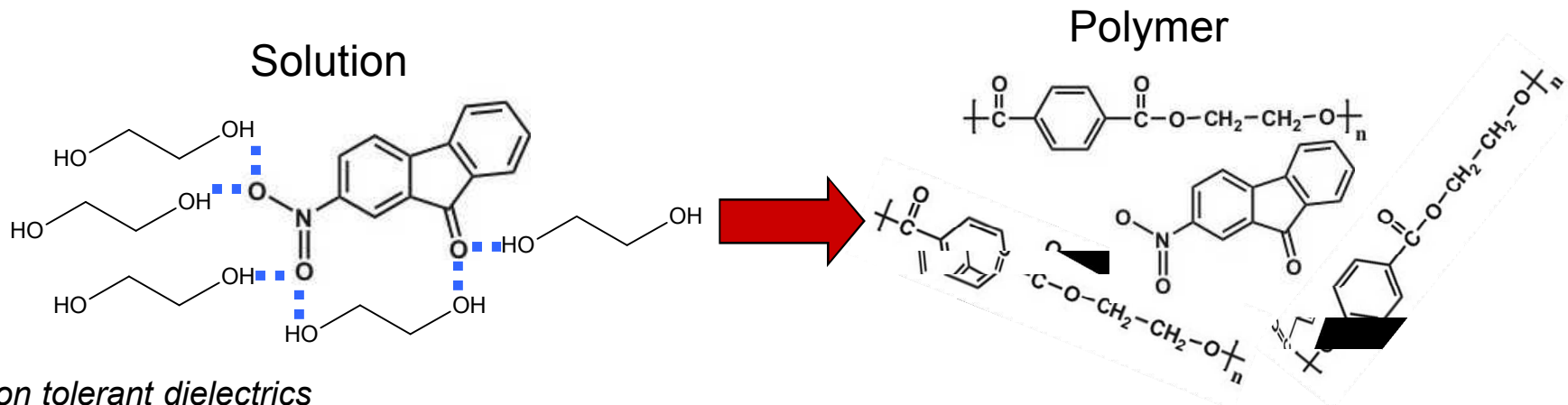
$$K_x = m_{d.S} m_{P.d} \exp(m_{d.S} + 1/m_{P.d} - 2) \exp(\chi_d^S - \chi_d^P)$$

$$\chi_{AB} = \frac{v_m (\delta_A - \delta_B)^2}{RT} \quad \delta = \left(\frac{\sum_i E_i}{\sum_i V_i} \right)^{1/2}$$

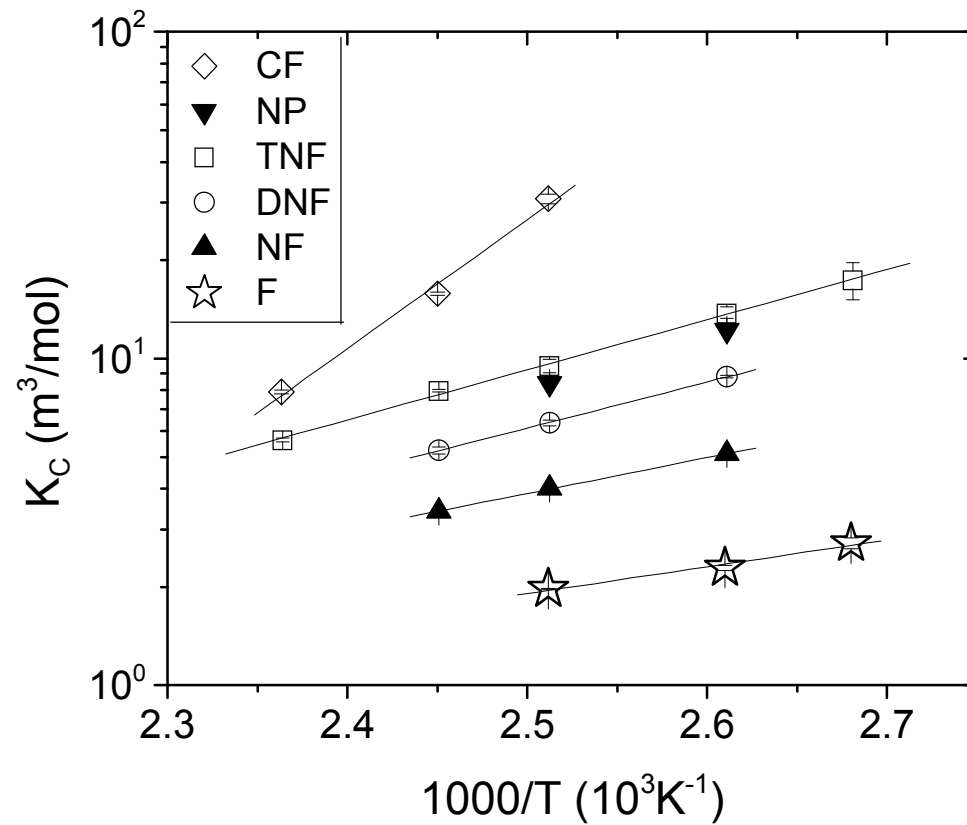
$$\gamma_d^{S(H)} \approx \exp(-2a)$$

Only one unknown in this set of equations: $a \equiv$ number of H-bonds per molecule

H-bonding in solution (ethylene glycol to dopant) has effect of decreasing partition coefficient



From slopes and magnitudes of K we can estimate the number of H-bonds



Dopant	<i>a</i>
F	4
NF	7
DNF	10
TNF	13
CF	-

FOTS, FODS, and FOMS

Fluorinated octyl trichlorosilane

FOTS

